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# **SERVICE MANUAL**

**UHF FM TRANSCEIVER** 

IC-P4AT IC-P4ET

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Icom Inc.

#### INTRODUCTION

This remine manual describes the latest service information for the IC-P4AT/ET UHF FM TRANSCEIVER at the time of publication.

4 versions of the IC-P4AT/FT have been designed. This service manual covers each version

MODEL	VERSION NO.	VERSION	SYMBOL
IC-P4ET	#04	Europe	EUR
	#05	U.S.A.	USA
IC-P4AT	#07	Australia	AUS
	#100	Asia	OEA

To uncrease quality, all electrical or mechanical parts and internal circuits are subject to change without notice or obligation.

#### DANGER

NEVER connect the transceiver to an AC outlet or to a DC power supply that uses more than 18 V. This will ruin the transceiver DO NOT expose the transceiver to rain, snow or any liquids.

DO NOT reverse the polarities of the power supply when connecting the

DO NOT apply an RF signal of more than 20 dRm (100 mW) to the antenna connector. This could damage the transceiver's front end.

#### ORDERING PARTS

- Be sure to include the following four points when ordering replacement parts: 1. 10-digit order numbers
- 2. Component part number and name
- Equipment model name and unit name
- 4. Quantity required

#### (SAMPLE ORDER)

1150000790 IC 901007 IC-P4AT/ET MAIN UNIT 5 pieces 8810001590 Screw PHPTM2 x 15.7K IC-PANT/FT Rear panel 10 pieces

Addresses are provided on the inside back cover for your convenience.

#### REPAIR NOTES

- Make sure a problem is internal before disassembling the transceiver
- 2 DO NOT open the transceiver until the transceiver is disconnected from its nower source
- 3. DO NOT force any of the variable components. Turn them slowly and
- 4. DO NOT short any circuits or electronic parts. An insulated tuning tool MUST be used for all adjustments
- 5. DO NOT keep power ON for a long time when the transceiver is defective. DO NOT transmit power into a signal generator or a sweep generator.
- 7. ALWAYS connect a 40 dB~50 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment. . .
- 8. READ the instructions of test equipment thoroughly before connecting equipment to the transceiver.



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#### SECTION 1 SPECIFICATIONS

#### GENERAL

Frequency coverage

 MODEL
 VERSION
 FREQUENCY COVERAGE

 IC-P4AT
 U.S.A.
 440~450 MHz

 Australia
 430~440 MHz

 Asia
 430~440 MHz

 IC-P4ET
 Europe
 430~440 MHz

• Mode : FM

• Tuning steps : 5, 10, 12.5, 15, 20, 25, 30 or 50 kHz

• Dial select steps : 100 kHz or 1 MHz

• Number of channels : Memory channels 100 Call channel 1

Scan edge channels 2

• Antenna impedance :  $50 \Omega$  (nominal) • Usable battery pack or case : BP-110 $\sim$ BP-114

External DC power supply : 6~16 V DC (negative ground)

• Current drain (at 13.8 V DC)

Transmit	High	1.8 A
Transmit	Low 1	950 mA
Danaina	Power saved	19 mA (typical)
Receive	Rated audio output	250 mA

• Usable temperature range :  $-10 \,^{\circ}\text{C} \sim +60 \,^{\circ}\text{C} \, (+14 \,^{\circ}\text{F} \sim +140 \,^{\circ}\text{F})$ • Frequency stability :  $\pm 5 \, \text{ppm} \, (0 \,^{\circ}\text{C} \sim +50 \,^{\circ}\text{C}; \, +32 \,^{\circ}\text{F} \sim +122 \,^{\circ}\text{F})$ 

• Dimensions (with BP-111) : 49 (W) × 105 (H) × 38.5 (D) mm

1.9 (W)  $\times$  4.1 (H)  $\times$  1.5 (D) in (Projections not included)

• Weight (with BP-111) : 280 g (9.9 oz)

#### TRANSMITTER

Output power (at 13.8 V DC)
 Modulation system
 5.0, 3.5, 1.5 W or 500 mW (selectable)
 Variable reactance frequency modulation

• Max. frequency deviation : ±5 kHz

• Spurious emissions : Less than −60 dB

• Microphone impedance :  $2 k\Omega$ 

• Heatsink duty cycle : Transmit: Receive=1 min.: 3 min.

#### RECEIVER

• Receive system : Double-conversion superheterodyne

• Intermediate frequencies : 1st 30.875 MHz

2nd 455 kHz

Sensitivity : Less than 0.16 μV for 12 dB SINAD

• Squelch sensitivity (threshold) : Less than 0.1 μV

• Selectivity : More than 15 kHz/-6 dB

Less than 30 kHz/-60 dB

• Spurious response rejection : Less than −60 dB

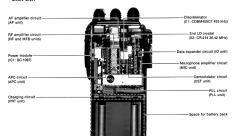
• Audio output power : 200 mW at 10 % distortion with an 8  $\Omega$  load

Audio output impedance : 8 Ω

All stated specifications are subject to change without notice or obligation.

#### SECTION 2 INSIDE VIEWS

#### MAIN UNIT



#### • LOGIC UNIT



### SECTION 3 CIRCUIT DESCRIPTION

#### 3-1 RECEIVER CIRCUITS

# 3-1-1 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

The antenna switching circuit functions as a low-pass filter while receiving and a resonator circuit while transmitting. The circuit does not allow transmit signals to enter receiver circuits.

Received signals pass through a two-stage Chebyschev low-pass filter ( $L2\sim L4$ ,  $C21\sim C25$ ) to suppress out-of-band signals. The filtered signals pass through a high-pass filter (L13, C30, C32, C60) and are then applied to the two-stage  $\lambda/4$  type antenna switching circuit (D7, D9, L5, L6, C26, C27). The signals are applied to the RF unit through the RF IN signal line.

#### 3-1-2 RF CIRCUIT (RF UNIT)

The RF circuit amplifies signals within the range of frequency coverage and filters out-of-band signals.

The signals from the antenna switching circuit are amplified at the 2 stage amplifiers (Q1 and Q2). The bandpass filters (L1, L2) employ the helical coils and suppress out-of-band signals. The filtered signals are applied to the 1st mixer circuit on the MAIN unit.

# 3-1-3 1ST MIXER AND IF CIRCUITS (MAIN AND DET UNITS)

The 1st mixer circuit converts the received signal to a fixed frequency of the 1st IF signal with a PLL output frequency. By changing the PLL frequency, only the desired frequency will be passed through a pair of crystal filters at the next stage of the 1st mixer.

The signals from the RF circuit are mixed at Q1 with a 1st LO signal coming from the PLL unit to produce a 30.875 MHz 1st IF signal. The 30.875 MHz 1st IF signal is obtained at L1 and is then applied to a pair of crystal filters (FI1) in order to obtain wide selection capability and to pass only the desired signals. The filtered signal is applied to a 1st IF amplifier (Q2) on the DET unit through the IFIN signal line and then to a 2nd mixer circuit.

# 3-1-4 2ND IF AND DEMODULATOR CIRCUITS (DET UNIT)

The 2nd mixer circuit converts the 1st IF signal to a 2nd IF signal. A double superheterodyne system (which converts receive signals twice) improves the image rejection ratio and obtains stable receiver gain.

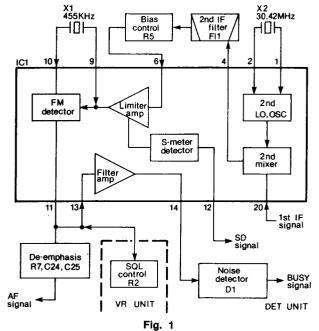
The 1st IF signal from Q2 is applied to a 2nd mixer section of IC1 (pin 20) and is then mixed with a 2nd LO signal for conversion to a 455 kHz 2nd IF signal.

IC1 contains the 2nd mixer, local oscillator circuit, limiter amplifier, quadrature detector circuit and active filter circuit. The local oscillator section and X2 generate 30.42 MHz for the 2nd LO signal.

The 2nd IF signal from the 2nd mixer (IC1, pin 4) passes through a high-quality ceramic filter (FI1) to suppress unwanted heterodyned frequency signals. It is then amplified at the limiter amplifier section (IC1, pin 6) and applied to the quadrature detector section (IC1, pin 10 and ceramic discriminator, X1) to demodulate the 2nd IF signal into an AF signal. The AF signal is output from IC1 (pin 11).

The AF signal output from IC1 (pin 11) is applied to the squelch circuit and de-emphasis circuit (R7, C24, C25). This de-emphasis circuit is an integrated circuit with frequency characteristics of -6 dB/octave. The resulting signal passes through the DETO signal line and is then applied to the AF amplifier circuit on the AF unit and the optional units (UT-50 TONE SQUELCH UNIT through J5 on the MAIN unit and UT-49 DTMF DECODER UNIT through J1 on the LOGIC unit).

#### • 2ND IF AND DEMODULATOR CIRCUITS



# 3-1-5 AF AMPLIFIER CIRCUIT (AF AND VR UNITS)

The AF amplifier circuit amplifies the demodulated signal to drive a speaker and includes an AF mute circuit.

The AF signal is applied to Q1 and Q2 on the AF unit. Q1 is an active filter that functions as a high-pass filter to suppress tone signals for the tone squelch operation. Q2 is also an active filter but functions as a low-pass filter to suppress higher noise signals.

The filtered signal is applied to the [VOL] control (R1) on the VR unit via the AF mute circuit (Q3). When the squelch is closed, Q3 cuts the AF signal as the AF mute switch. The AF signal is power-amplified at the AF power amplifier (IC1) to drive the speaker.

The AF amplifier regulator (Q4~Q6) supplies sufficient voltage to drive the AF power amplifier. The AFS signal from the MAIN unit controls Q6 and mutes AF output while receiving no signal or no specified tone/DTMF signal.

# 3-1-6 NOISE SQUELCH CIRCUIT (DET AND VR UNITS)

A noise squelch circuit cuts out AF signals when no RF signal is received. By detecting noise components in the AF signals, the squelch circuit switches the AF mute switches.

Some noise components in the AF signal from IC1 (pin 11) are applied to an active filter section (IC1, pin 13). The [SQL] control (R2) on the VR unit is connected in parallel to IC1 (pin 13) to adjust pin 13 input level.

The active filter section in IC1 amplifies the noise components of frequencies 20 kHz and above. The noise signals are output from IC1 (pin 14) and are then rectified by D1 for conversion to DC voltage.

The rectified voltage triggers the squelch switch (Q1). The collector of Q1 outputs the squelch signal. The signal is applied to the CPU (IC1, pin 33) on the LOGIC unit through the BUSY signal line. The CPU outputs the BUSY LED signal.

The "RMUTE" signal, decoded at the output expander (IC1, pin 6) on the IO unit, activates the AF mute circuit (Q3) on the AF unit to cut the AF signal. The BUSY LED signal is applied to Q8 on the LOGIC unit, turning OFF the receive indicator.

# 3-1-7 S-INDICATOR CIRCUIT (DET, MAIN AND LOGIC UNITS)

The S-indicator circuit indicates the signal strength on the LCD.

The S-meter signal is output from the limiter amplifier section in IC1 and is then detected at the S-meter detector section in IC1. The detected signal is output from IC1 (pin 12) through the SD signal line. The signal is applied to an S/RF comparator (IC2, pin 3) on the LOGIC unit as the "S" signal.

IC2 (pin 1) receives an S-indicator reference signal from the CPU (IC1, pins  $20{\sim}23$ ) using the D/A converter (R26 ${\sim}$ R29). These pins increase the reference signal level.

When the reference signal becomes greater than the S signal, IC2 (pin 4) outputs "LOW." The CPU detects the signal strength level using the outputs from IC1 (pins  $20\sim23$ ) and indicates the signal strength level on the LCD when receiving the "LOW" signal.

#### AF SIGNAL CURRENT R+5S line RMUT LOGIC AF UNIT VR UNIT Q2 Volume Q1 control AF signal from DET unit C6 R1 C17 AF amp D1 IC1 05 R14 5V line Fig. 2

#### 3-2 TRANSMITTER CIRCUITS

# 3-2-1 MICROPHONE AMPLIFIER CIRCUIT (MIC UNIT)

The microphone amplifier circuit amplifies audio signals with +6 dB/octave pre-emphasis from the microphone to a level needed for the modulation circuit.

The AF signals from the built-in condenser microphone or from the [MIC] jack are applied to IC1a (pin 3). IC1a functions as the microphone amplifier and the limiter with +6 dB/octave pre-emphasis characteristics.

The output signals from IC1a (pin 1) pass through a splatter filter circuit (IC1b) which eliminates signal components greater than 3 kHz. Pin 7 of IC1b outputs a "MOD" signal. The "MOD" signal is applied to the modulation circuit on the VCO unit.

#### 3-2-2 MODULATION CIRCUIT (VCO UNIT)

The modulation circuit modulates the VCO oscillating signal (RF signal) using the microphone audio signals.

The "MOD" signal changes the reactance of a diode (D3) to modulate the oscillated signal at the VCO circuit (Q1, D1). The oscillated signal is buffer-amplified at Q3 and Q4 on the PLL unit and is then re-amplified at Q9 on the MAIN unit. The buffer-amplified signal passes through the transmit/receive switching circuit (D14) and is then applied to the drive amplifier circuit.

# 3-2-3 DRIVE AMPLIFIER CIRCUIT (MAIN UNIT)

The drive amplifier circuit amplifies the VCO oscillating signal to the needed level at the power amplifier.

The signal from the transmit/receive switching circuit (D14) is amplified at the pre-drive amplifier (Q7) and is then re-amplified at a drive amplifier (Q6) to obtain 20 mW.

The control voltage from the APC circuit is applied to the collector of Q6 and Q7 for stable RF output power from a power amplifier (IC1).

# 3-2-4 RF POWER AMPLIFIER (MAIN UNIT)

IC1 is a power module which provides a stable 5 W (at DC 13.8 V) of output power.

The RF signal from the drive amplifier (Q6) is applied to the power amplifier (IC1, pin 1). The amplified signal is output from IC1 (pin 4). The output signal is applied to the antenna connector through the APC detector circuit, the antenna switching circuit and the low-pass filter circuit.

# 3-2-5 APC CIRCUIT (MAIN. APC AND IO UNITS)

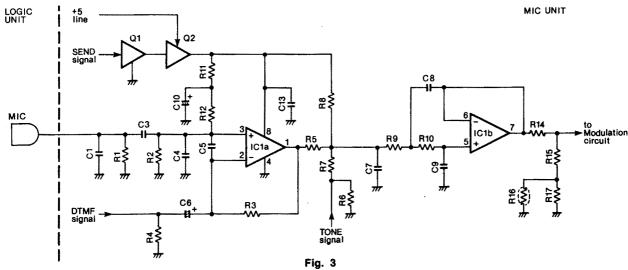
The APC circuit protects the power module (IC1) from a mismatched output load and selects HIGH and LOW output power.

The output power from the power module (IC1, pin 4) is applied to the APC detector circuit (L10, D10, D11) to obtain mismatched voltage. When the antenna impedance is matched at  $50\,\Omega$ , the detected level is at its minimum. However, when antenna impedance is mismatched, the detected voltage is higher than when it is matched.

The detected voltage is applied to a differential amplifier circuit (Q3b) on the APC unit. The APC reference voltage is determined by the power output control circuit (R2~R6) on the IO unit and is then applied to the base of Q3a on the APC unit through the PCON signal line.

When the antenna impedance is mismatched, the base voltage of Q3b exceeds the reference voltage. The collector voltage of Q3b decreases.

#### • MICROPHONE AMPLIFIER CIRCUIT



The current from the differential amplifier circuit (Q3a, Q3b) is amplified at Q2 to control Q1. The control voltage changes the supply voltage to Q6 and Q7 on the MAIN unit. This decreases the output power from the drive amplifier (Q6) until the base voltage of Q3b reaches the same level as the voltage of Q3a.

# 3-2-6 POWER OUTPUT CONTROL CIRCUIT (IO UNIT)

The power output control circuit (R2~R6) selects the output levels (HIGH, LOW 1~LOW 3) and controls the RF output power with the APC reference voltage.

The output signals from IC2 (pins 13 and 14) are converted from digital to analog at the power output control circuit (R2 $\sim$ R6) to select the four output levels (HIGH, LOW 1 $\sim$ LOW 3).

# 3-2-7 TX MUTE CIRCUIT (IO, APC AND MAIN UNITS)

The TX mute circuit interrupts the transmission by controlling the TMUTE signal.

The "TMUTE" signal is output from IC3 and controlled by the outputs from IC1 (pin 7) and Q2 on the IO unit. When Q4 and Q5 on the APC unit are turned OFF to interrupt the transmission by the "TMUTE" signal, the bias voltages are prevented from entering Q6, Q7 and IC1 on the MAIN unit.

# 3-2-8 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

The antenna switching circuit applies the received signal to the receiver circuit and the transmitter signal to the antenna connector.

When transmitting, D7 and D9 are turned ON. The RF output signal is not permitted to enter the receiver circuit. The signal passes through D9 and is then applied to the high-pass filter (L13, C30, C32, C60). The filtered signal passes through the low-pass filter (L2~L4, C21~C25) and is then applied to the antenna connector. The low-pass filter suppresses high harmonic components.

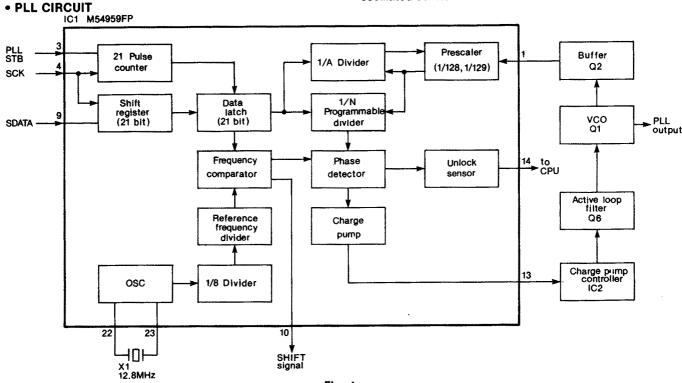
#### 3-3 PLL CIRCUITS

#### 3-3-1 GENERAL

PLL circuits provide steady oscillation of the transmit frequency and the receive 1st LO frequency. The PLL output frequency is controlled by the divided ratio (N-data) of the programmable divider.

#### 3-3-2 PLL CIRCUIT (PLL AND VCO UNITS)

The PLL circuit, using a one-chip modulus prescaler (IC1) on the PLL unit, directly generates the transmit frequency and the receive 1st LO frequency with the VCO (Q1, D1) on the VCO unit. The modulus prescaler (IC1) sets the dividing ratio based on serial data from the CPU (IC1) on the LOGIC unit and compares the phase of the VCO signal with the reference oscillator frequency. The PLL IC (IC1) detects the out-of-step phase and outputs it from IC1 (pin 13). A reference frequency is oscillated at X1.



# 3-3-3 REFERENCE OSCILLATOR CIRCUIT (PLL UNIT)

A 12.8 MHz reference frequency is produced by X1. The frequency is adjusted with C17. The reference frequency is divided by 2560 to obtain 5 kHz.

#### 3-3-4 VCO CIRCUIT (VCO UNIT)

The VCO circuit (Q1, D1) generates the transmit frequency and the receive 1st LO frequency. The varactor diode (D1) provides frequency control. While transmitting, IC1 (pin 10) becomes "HIGH" to turn D2 OFF. Hence, C6 is added for oscillation. At this time, the microphone signal is applied to D3 cathode for modulation. While receiving, IC1 (pin 10) becomes "LOW" to turn D2 ON. Hence, C6 is ignored for oscillation. The output signal from the emitter of Q1 is buffer-amplified at Q2 on the PLL unit and is then applied to PLL IC (IC1, pin 1). On the other hand, the output signal from the collector of Q1 is buffer-amplified at Q3 and Q4 on the PLL unit and is then re-amplified at Q9 on the MAIN unit. These buffer amplifiers amplify VCO oscillation and do not permit the later circuit to affect the VCO oscillation. The amplified signal is applied to the transmit/receive switching circuit (D14).

# 3-3-5 PROGRAMMABLE DIVIDER AND PHASE DETECTOR CIRCUITS (PLL UNIT)

The programmable divider shifts the dividing ratio, depending on the operating frequency, with a prescaler and determines the VCO oscillating frequency.

The phase detector circuit detects the off-phase components of the VCO frequency using a stable reference frequency.

IC1 is a one-chip PLL IC that contains a two-modulus prescaler, a pulse counter, a programmable divider and a phase detector. IC1 accepts up to 500 MHz inputs.

The input signal from the PLL IC (IC1, pin 1) passes through the two-modulus prescaler and the programmable counter sections of IC1. A 12.8 MHz reference frequency from X1 is applied to IC1 (pin 23) and passes through a programmable reference counter section of IC1. Both of the divided signals are compared at a phase detector section of IC1. The phase-detected signal (pulse signal) is output from IC1 (pin 13).

#### 3-3-6 LOOP FILTER CIRCUIT (PLL UNIT)

The phase-detected signal (pulse signal) from IC1 (pin 13) passes through the switching IC (IC2) and is then applied to the active loop filter (Q6, C40, C43, R27, R28). The active loop filter converts the pulse signal to DC voltage while increasing the DC voltage range. The PLL lock voltage changes the rectance of a varactor diode (D1) on the VCO unit.

#### 3-3-7 UNLOCK SENSOR CIRCUIT (PLL UNIT)

When the PLL circuit is unlocked, IC1 (pin 14) becomes "HIGH." The "HIGH" signal is applied to the CPU (IC1, pin 31) as an unlock signal.

#### 3-4 POWER SUPPLY CIRCUITS

#### 3-4-1 VOLTAGE LINES

LINE	DESCRIPTION
HV	The external DC power from the DC power connector.
VCC	This voltage passes through [VOL] control (R1) on the VR unit and is then applied to the 5 V regulator circuit (IC1) on the REG unit. This voltage line changes depending on the battery pack type: 7.2 V (BP-111~BP-113), 12.0 V (BP-114)
+5	Common 5 V converted from the VCC line at the 5 V regulator circuit (Q1, Q2, D3) using IC1 output as the reference voltage on the REG unit. This regulator circuit is composed of a complementary connection to ensure high current amplification and supplies stable output voltage continuously with good temperature characteristics in all modes.
+5S	5 V controlled by the power saver function. When the power saver is turned ON, a "PSC" signal from the output expander (IC1, pin 13) on the IO unit interrupts the "+5S" line intermittently to save power. This voltage is converted from the VCC line at Q3, Q4 and D1 using IC2 output as the reference voltage on the REG unit. This regulator circuit forms a complementary circuit.
R+5\$	Receive 5 V controlled by the power saver function and a "SEND" signal from the output expander (IC1, pin 14) on the IO unit. This voltage is converted from the VCC line at Q5, Q6 and D2 using IC3 output as the reference voltage on the REG unit. This regulator circuit forms a complementary circuit.
T+5	Transmit 5 V controlled by a "TMUT" signal from the output expander (IC2, pins 13 and 14) on the IO unit. This voltage is converted from the VCC line at Q4, Q5 and D2 on the APC unit. The power output control circuit (R2~R6) on the IO unit provides the reference voltage. This regulator circuit forms a complementary circuit.

# 3-4-2 CPU POWER SUPPLY CIRCUIT (LOGIC UNIT)

When the power switch is turned OFF and the external battery pack is discharged, DC voltage is applied to the CPU (IC1, pin 97) via R2 from the lithium backup battery (BT1) installed in the transceiver to provide backup for the memory contents.

When the attached battery pack voltage or external DC power is applied to the transceiver, BT1 is charged by the current regulator (Q1).

#### 3-4-3 +5S AND R+5S SWITCHING **CIRCUITS (REG UNIT)**

The IC-P4AT/ET has a power saver function to reduce current consumption to approx. 1/4.

The PSC (Power Saver Control) signal is applied to IC2. IC2 controls the +5S regulator (Q3, Q4, D1) to turn ON and OFF the +5S voltage.

PSC and SEND signals are applied to IC3. IC3 controls the R+5S regulator (Q5, Q6, D2). R+5S turns OFF during the power save period or transmitting.

#### 3-4-4 CHARGING CIRCUIT (PRT UNIT)

The DC voltage from the [DC 13.8V] jack is applied to the current control circuit (Q1~Q3, D1, D2) to charge an attached battery pack.

When the external battery pack is attached, the current from D1 charges the attached battery pack.

The charging current is determined the resistor inside battery pack. The CHG terminal is connected to the battery pack internal reistor.

#### 3-5 OTHER CIRCUITS

#### 3-5-1 AF 7 V REGULATOR CIRCUIT (AF UNIT)

The AF 7 V regulator circuit (Q4~Q6) produces a regulated 7 V to the AF amplifier (IC1) when the squelch is open or the [MONI/DSEL] switch is pushed. This circuit is controlled by the AFS signal line. R14 and R15 provide the reference voltage.

#### 3-5-2 DIMMMER CIRCUIT (LOGIC UNIT)

The dimmer circuit consists of a regulator circuit (Q3, Q4, D4) and the backlight LEDs (DS3~DS6 on the LOGIC unit, DS1~DS4 on the TENKEY unit). This circuit drives the backlight LEDs and ensures that brightness does not change even with a change of power supply.

When the [LIGHT] switch is pushed, the CPU (IC1, pin 30) outputs a "HIGH" signal. The signal is applied to the regulator circuit (Q3, Q4, D4) to light up the backlight LEDs (DS3~DS6 on the LOGIC unit, DS1~DS4 on the TENKEY unit).

#### 3-5-3 1750 Hz TONE CALL CIRCUIT (LOGIC UNIT)

A 1750 Hz tone call is provided for IC-P4ET.

When the [PTT] switch is quickly pushed and then briefly held down a second time or when the [PTT] switch is pushed with the [LIGHT] switch, the CPU (IC1, pin 15) outputs a 1750 Hz tone signal. R45 adjusts the 1750 Hz tone deviation. The signal passes through R46 and is then applied to the AF unit and VR unit through the AF1 signal line.

#### 3-5-4 CPU RESET CIRCUIT (LOGIC UNIT)

This circuit resets the CPU (IC1) with a reset IC (IC4). The reset IC (IC4) detects the increase and decrease of the +5 voltage line to control the RST port of the CPU (IC1, pin 26) when the [PWR/VOL] control is turned ON and OFF.

When the [PWR/VOL] control is turned ON, the RST port of the CPU (IC1, pin 26) becomes "HIGH." The CPU (IC1) starts operation.

When the [PWR/VOL] control is turned OFF, the RST port of the CPU (IC1, pin 26) becomes "LOW." The CPU (IC1) stops operation.

CPU initialization requires a pulse input via pin 10 and the [CLR] key operation. While turning the power ON and holding the [FUNC] switch, the AND gate IC (IC3) outputs the pulse signal.

#### 3-5-5 TRANSMIT/RECEIVE INDICATOR CIRCUIT (LOGIC UNIT)

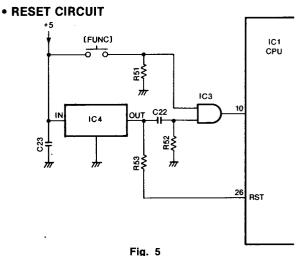
The transmit/receive indicator (DS2) uses a 2-input LED and lights up in red or green.

The transmit indicator lights up in red when transmitting with the T+5 voltage.

The receive indicator lights up in green when the squelch opens with the "BUSY LED" signal from the CPU (IC1, pin 14) through the inverter (Q8).

#### 3-5-6 CLOCK OSCILLATOR CIRCUIT (LOGIC UNIT)

IC1 oscillates the 798.642 kHz system clock signal with X1. IC1 oscillates the 32.768 kHz clock signal for the built-in clock with X2.



## **3-6 PORT ALLOCATIONS**

#### • IC1 CPU (LOGIC UNIT)

PORT NAME	PIN NUMBER	DESCRIPTION	
OSC1	8	Input port for the CPU system clock signal.	
OSC2	9	Output port for the CPU system clock signal.	
RESET	10	When a "HIGH" signal is applied to this port, either the CPU is initialized or changes to standby mode.	
X1	11	Input port for the CPU clock signal.	
X2	12	Output port for the CPU clock signal.	
BUSY LED	14	Output port for the transmit/receive indicator. This port becomes "LOW" when the squelch opens. The transmit/receive indicator lights up in green.	
TONE OUT	15	Outputs a 1750 Hz tone signal. (IC-P4ET only)	
PTT	16	The CPU detects that the [PTT] switch has been pushed when this port becomes "LOW."	
DIAL UP	17	Input port for the up signal of the main dial.	
DIAL DN	18	Input port for the down signal of the main dial.	
TOE	19	Outputs an enable signal for the UT-49 DTMF DECODER UNIT.	
KEYS0~ KEYS3	20~23	Output strobe signals for the key board, initial and key matrix and D/A converter counting signal alternately in an interval.	
SIN	24	Inputs a resulting signal from the S/RF meter comparator (IC2) to indicate the CPU counting level on the function display.	
RST	26	Detects a signal for the standby mode of the CPU. The CPU enters the standby mode when the port becomes "LOW."	
STD	27	Becomes "LOW" when the CPU decodes the received DTMF code.	
FUNC	28	Input port for the [FUNC] switch.	
LAMP	29	Input port for the [LIGHT] switch.	
LAMPO	30	Becomes "HIGH" when the backlight LEDs (DS3~DS6 on the LOGIC unit; DS1~DS4 on the TENKEY unit) light up.	
UL	31	Detects a PLL unlock signal. This port becomes "HIGH" when the PLL is unlocked.	
TSQL	32	Input port for an optional unit. This port becomes "HIGH" when the tone squelch opens. (UT-50 TONE SQUELCH UNIT) This port becomes "LOW" when the UT-51 PROGRAMMABLE TONE ENCODER UNIT is installed.	
BUSY	33	Detects a squelch signal. This port becomes "HIGH" when the squelch opens.	
IOSTB	34	Outputs strobe signals for serial data to the I/O expander ICs (IC1, IC2) on the IO unit.	

PORT NAME	PIN NUMBER	DESCRIPTION
SCK	35	Outputs clock signals for serial data.
PLL STB	36	Outputs strobe signals for serial data to the PLL IC (IC1) on the PLL unit.
SDATA	37	Outputs serial data synchronized with the SCK signal.
R30~R33	38~41	Input ports for the initial and key matrix.
R42~R45	42~45	Input ports for the keyboard and DTMF code from UT-49 DTMF DECODER UNIT.
H/L	48	Input port for the [H/L/DTMF] switch.
TONEC, TONER	98, 99	Outputs a DTMF code signal.

#### • IC1 OUTPUT EXPANDER (IO UNIT)

PORT NAME	PIN NUMBER	DESCRIPTION
AF ON	4	Output port for the AF muting signal which mutes the AF power amplifier (IC1) on the AF unit.
MIC	5	Output port for the microphone muting signal. When transmitting a tone signal, this signal line goes to ground.
RMUTE	6	Output port for the receive muting signal which mutes audio power. When emitting a beep tone, this port outputs the muting signal and the AF ON port does not output it.
TMUTE	7	Output port for the transmit muting signal which mutes RF power.
MODE	11	Output port for a mode signal.
CPC	12	Outputs a control signal to cut off the loop filter while the power saver function is activated.
PSC	13	This port becomes "HIGH" while the power saver function is activated.
SEND	14	Output for the transmit/receive signals. This port becomes "HIGH" while transmitting.

#### • IC2 OUTPUT EXPANDER (IO UNIT)

PORT NAME	PIN NUMBER	DESCRIPTION	
BA2, BA3	5, 6	Outputs the control signals for the RF bandpass filter.	
+5, PCON	13, 14	Outputs the control signals for the output power selecting circuit. These signals are converted into the APC reference voltage with the D/A converter (R2~R6).	

#### 3-7 OPTIONAL UNITS

#### 3-7-1 UT-49 DTMF ENCODER UNIT

The UT-49 DTMF ENCODER UNIT provides pager and code squelch functions.

The "DETO" signal from the DET unit passes through J1 on the LOGIC unit and is then applied to the DTMF decoder IC (IC1, pin 2). The input signal passes through the filter circuit in IC1 and is then applied to the signal detector circuit in IC1. When the double tone signal is detected, pin 15 of IC1 becomes "HIGH." Therefore, the CPU (IC1, pin 27) on the LOGIC unit becomes "LOW" and then decodes the received DTMF code. The CPU (IC1, pin 19) outputs an enable signal to read out the 4-bit binary outputs (Q1~Q4) from the UT-49 DTMF ENCODER UNIT.

The CPU (IC1, pins 98 and 99) on the LOGIC unit outputs a DTMF code signal. The output signal is applied to R35 for the DTMF deviation adjustment. The signal is applied to the MIC unit through the "DTMF" signal line.

#### 3-7-2 UT-50 TONE SQUELCH UNIT

The UT-50 TONE SQUELCH UNIT provides pocket beep, tone squelch and programmable tone encoder functions.

IC1 encodes and decodes the subaudible tone frequency signals of 67.0 Hz $\sim$ 250.3 Hz. The serial data from the CPU (IC1) on the LOGIC unit passes through J5 on the MAIN unit and is then applied to a serial/parallel converter (IC2) to set the tone signals.

When IC1 (pin 12) becomes "LOW," IC1 (pin 26) outputs the tone signal programmed in IC2. The output signal from IC1 (pin 26) is applied to R10 for the tone deviation adjustment. The signal passes through the tone signal output buffer amplifier (Q4) and is then applied to the MIC unit through the "TONE" signal line.

The "DETO" signal from the DET unit passes through J5 on the MAIN unit and is then applied to IC1 (pin 29). The input signal is compared with the tone signal programmed in IC2. Pin 23 of IC1 becomes "HIGH" during the successful decode.

# 3-7-3 UT-51 PROGRAMMABLE TONE ENCODER UNIT

The UT-51 PROGRAMMABLE TONE ENCODER UNIT accesses a repeater requiring a subaudible tone.

IC1 encodes the subaudible tone frequency signals of 67.0 Hz $\sim$ 250.3 Hz. The serial data from the CPU (IC1) on the LOGIC unit passes through J5 on the MAIN unit and is then applied to a serial/parallel converter (IC2) to set the tone signals. IC2 supplies the 6-bit parallel data to pins 8 $\sim$ 13 of IC1.

The 6-bit parallel data from IC2 passes through the programmable counter section of IC1. A 3.579545 MHz reference frequency from X1 is applied to a programmable counter section of IC1. The divided signal is output from IC1 (pin 1) and is then applied to R5 for the tone deviation adjustment. The signal passes through the tone signal output buffer amplifier (Q1) and is then applied to the MIC unit through the "TONE" signal line.

#### • UT-51 PROGRAMMABLE TONE ENCODER UNIT

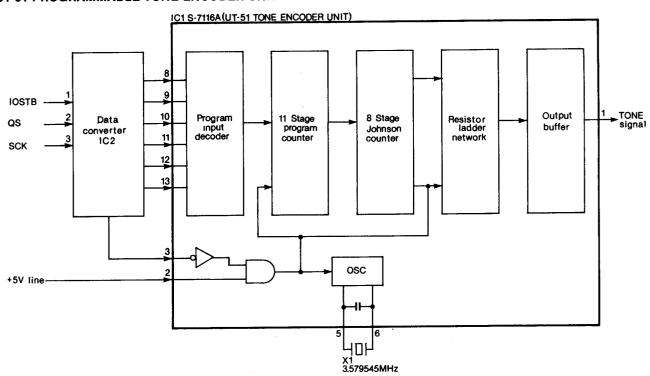


Fig. 6

#### **MECHANICAL PARTS AND DISASSEMBLY** SECTION 4

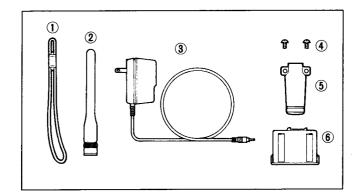
#### **4-1 FRONT PANEL**

LABEL Number	ORDER NO.	DESCRIPTION	QTY.	LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.
1	8610007640	Knob N177 [SQL], [PWR/VOL]	2	32	5030000720	LCD LD-BU5385J (E-5561)	1
2	8610007650	Knob N178 [MAIN DIAL]	1	33	8930022110	LCD holder	1
3	8830000710	VR nut (G)	3	34	8930022150	LCD rubber	1
4	8210006610	1144 top panel	1	35	8810005740	Screw FH B0 No. 0 M2×3	6
5	8930022230	1144 top seal	1	36	8110004510	1144 PCB cover	1
6	8930022121	1144 VR plate-1	1	37	8930022640	1144 U-rubber	1
7	8810005860	Screw No. 0 M2 × 3 NI	3	38	8930022650	1144 L-rubber	1
8	8810005700	Screw No. 0 M2×4 ZK	2	39	8930010330	Insulate plate AO	1
	0000001100	Encoder SW-122 (RK097103H)		40	8210006620	1144 10 keyboard	1
9	2260001400	[MAIN DIAL]	1		8210006691	1144 front panel (A)-1	1
•	7010001150	Variable resistor RK0971110051A			8210006691	(incl. window panel) P4AT	'
10	7210001450	(10 KB) [SQL]	1	41)	0010000701	1144 front panel (B)-1	1
	7010001110	Variable resistor RK097111101NA			8210006701	(incl. window panel) P4ET	'
10	7210001440	(10 KA) [PWR/VOL]	1	42	8810004450	Screw PH M2×8 ZK	1
(2)	0.450000070	Connector HEC2711-01-020		43	8850001230	Lug washer	1
(12)	6450000870	[DC 13.8 V]	1	- O	CE10010010	Connector BNC-RM-F1	
13	6450001060	Connector HSJ1493-01-010 [SP]	1	44	6510013810	[ANTENNA CONNECTOR]	1
14)	6450000130	Connector HSJ1102-01-540 [MIC]	1	45)	8930022630	1144 PTT rubber	1
15)	8810000120	Screw PH M2.6 × 3	1	46	8930014961	752 rainproof cap-1	1
16	8930016240	Fiber insulate plate (D)	1	47)	8810006460	Screw FH M2 × 3	1
17	8510005960	IF shield plate	1	48	8810001560	Screw PH PT M2 × 15 ZK	3
18	8810006620	Screw No. 0 M2 × 3.5 NI	4	49	8010007602	Hole bush (A)-2	2
(19)	8510005830	CO-PLL shield case cover	1	50	8810006950	Screw PH B0 No. 0 M2×4 ZK	2
20	8510005850	752 PLL shield case	1	<u>(51)</u>	8930022720	1144 release button	1
21)	8510005841	752 PLL shield case cover-1	1	52	8930023082	1144 slider-2	1
22	8810004800	Screw PH B0 No. 0 M2×4	4	53	8930022140	1144 release spring	1
23	8930022980	1144 LOGIC spring	1	54	8930022131	1144 lock angle-1	1
24	7700000861	Microphone WM-62A103	1	<b>55</b>	8850000110	Flat washer M2 NI BS	2
25	8930014940	752 Microphone holder	1	56	8930014912	Lamp button-2	1
26	8930018080	Speaker ring	1	<b>§7</b>	8010011820	1144 rear panel	1
27	2510000530	Speaker T028S14I0810	1	58	8930022950	1144 contact shield	1
28	8930023010	Insulate plate CE	1	59	8210006600	1144 contact panel	1
29	8510007440	1144 front shield	1	60	8810006940	Screw PH M2×2	2
30	6910006640	LCD reflector ALF39.5 × 24.5 × 0.58	1	<b>61</b>	8930022100	1144 contact terminal	3
31)	8930023130	LCD contact strip SRCN-1144W	2				

Screw abbreviations

B0: Self-tapping screw PH: pan head FH: Flat head BS: Brass NI: Nickel ZK: Black

#### **4-2 ACCESSORIES**



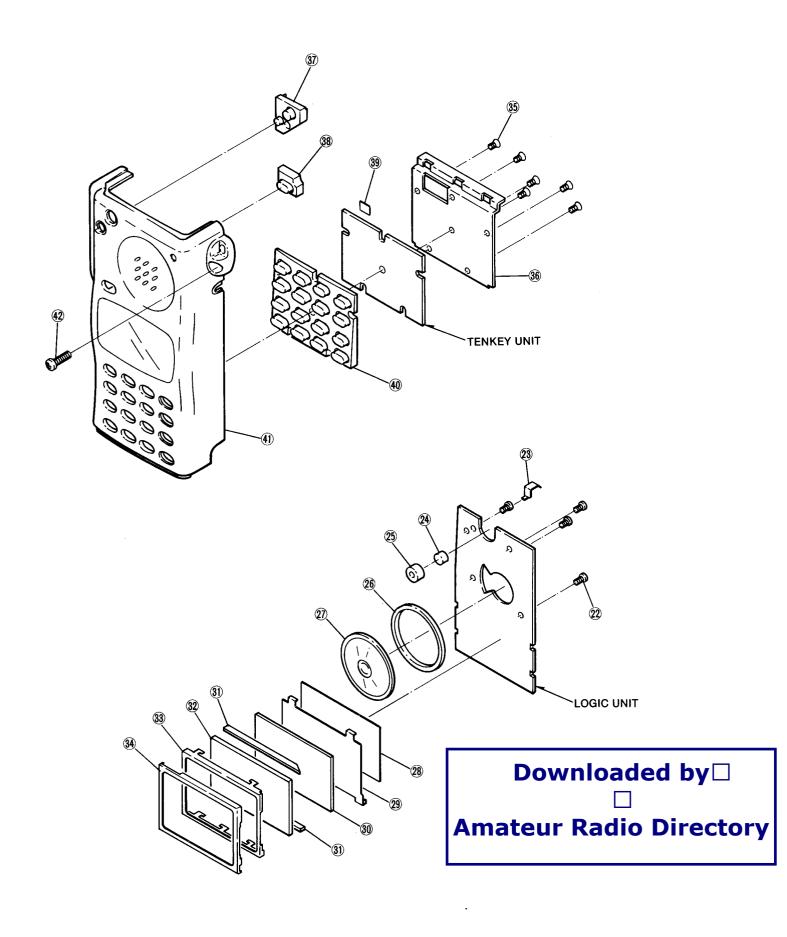
LABEL NUMBER ORDER NO.		DESCRIPTION	QTY.
1	8010011960	Handstrap HK-005	1
2	Optional product	FA-430BD Flexible antenna	1
	Optional product	Wall charger BC-73D (#04)	1
		Wall charger BC-73E (#09)	1
3		Wall charger BC-74A (#05)	1
		Wall charger BC-74V (#07)	1
4	8810005730	Screw BuH M3 × 3 ZK BS	2
(5)	8010008620	752 belt clip	1
6	Optional product	Battery pack BP-111	1

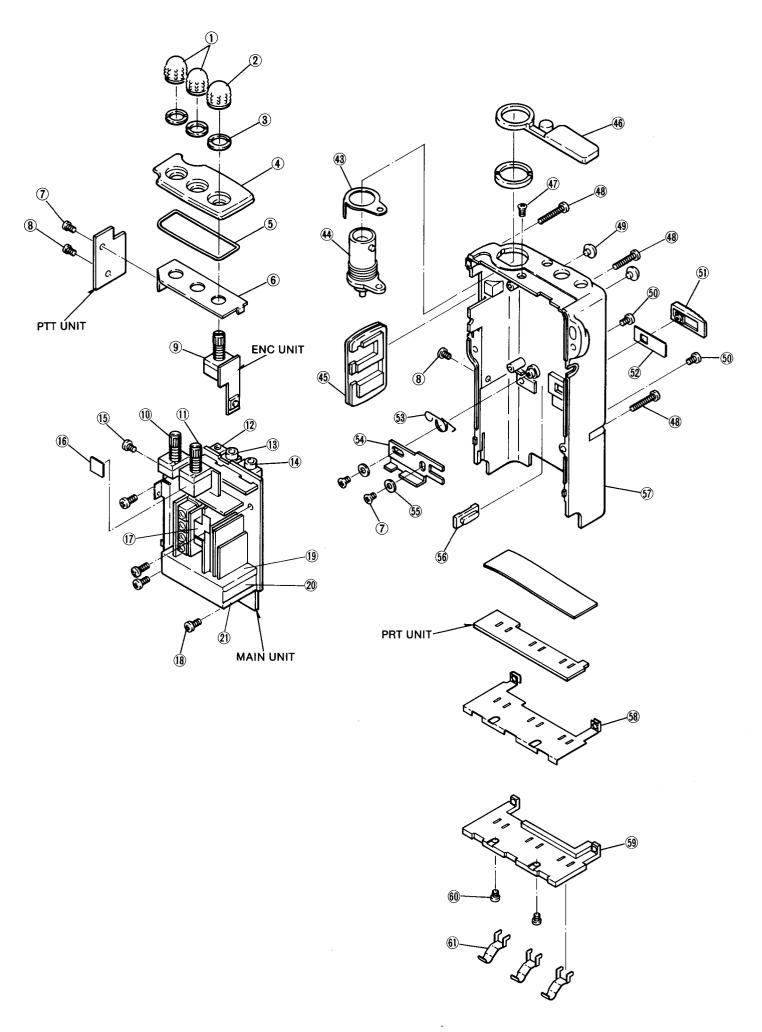
Screw abbreviations

BuH: Button head

BS: Brass

ZK: Black





### SECTION 5 PARTS LIST

#### [MAIN UNIT]

#### ORDER REF. DESCRIPTION SC1097 IC1 1150000720 IC Q1 1530002560 S. TRANSISTOR 2SC4403-3-TR 1510000510 S. TRANSISTOR 2SA1576 T107 R 03 S. TRANSISTOR DTC144EU T107 1590000430 Q4 S. TRANSISTOR 2SC2954-T2B Q6 1530002340 Q7 1530002560 S. TRANSISTOR 2SC4403-3-TR S. TRANSISTOR 2SA1576 T107 R Q8 1510000510 Q9 1530002560 S. TRANSISTOR 2SC4403-3-TR D1 1790000590 S. DIODE MA110 (TW) S. DIODE DA204U T107 D2 1750000130 D7 1790000450 S. DIODE MA862 (TX) **DAN202U T107** 1160000060 S. DIODE **D8** D9 1750000080 S. DIODE 1SS153-T2 1790000490 S. DIODE HSM88AS-TR D10 S. DIODE HSM88AS-TR 1790000490 D11 1790000590 S. DIODE MA110 (TW) D12 DA204U T107 1750000130 S. DIODE D13 D14 1790000450 S. DIODE MA862 (TX) 1790000680 S. DIODE SB20-03P-TD D15 MONOLITHIC 30M15B (FL-76) FI1 2010000230 6150003210 COIL LS-319 L1 6110001990 COIL LA-223 L2 LA-223 L3 6110001990 COIL L4 6110001990 COIL LA-223 L5 LA-223 6110001990 COIL COIL LA-223 L6 6110001990 6110001990 COIL LA-223 L7 L8 6110001990 COIL LA-223 6200000910 S. COIL LQN 2A 82NM L9 L10 6110001990 COIL LA-223 6200000100 S. COIL LQN 2A 22NM L11 **LQN 2A 18NM** 6200000090 S. COIL L12 L13 6110001990 COIL LA-223 6200000120 S. COIL LQN 2A 39NM L14 7030003700 S. RESISTOR ERJ3GEYJ 154 V (150 kΩ) R1 ERJ3GEYJ 683 V (68 kΩ) R2 7030003660 S. RESISTOR 7030003520 S. RESISTOR ERJ3GEYJ 472 V (4.7 kΩ) R3 ERJ3GEYJ 102 V (1 kΩ) R4 7030003440 S. RESISTOR ERJ3GEYJ 471 V (470 Ω) R6 7030003400 S. RESISTOR ERJ3GEYJ 474 V (470 kΩ) R7 7030003760 S. RESISTOR R8 7030003400 S. RESISTOR ERJ3GEYJ 471 V (470 Ω) S. RESISTOR ERJ3GEYJ 471 V (470 Ω) R9 7030003400 ERJ3GEYJ 103 V (10 kΩ) R10 7030003560 S. RESISTOR 7030003450 S. RESISTOR ERJ3GEYJ 122 V (1.2 kΩ) R11 ERJ3GEYJ 102 V (1 kΩ) R12 7030003440 S. RESISTOR R13 7030003440 S. RESISTOR ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 223 V (22 kΩ) R15 7030003600 S. RESISTOR 7510000070 **THERMISTOR** ERT-D2FHL 503S R16 S. RESISTOR ERJ3GEYJ 151 V (150 Ω) R17 7030003340 R18 7030003400 S. RESISTOR ERJ3GEYJ 471 V (470 Ω) R19 7030003500 S. RESISTOR ERJ3GEYJ 332 V (3.3 kΩ) ERJ3GEYJ 822 V (8.2 kΩ) R20 7030003550 S. RESISTOR 7030003510 S. RESISTOR ERJ3GEYJ 392 V (3.9 kΩ) R21 ERJ3GEYJ 471 V (470 Ω) 7030003400 S. RESISTOR R22 ERJ3GEYJ 100 V (10 Ω) R23 7030003200 S. RESISTOR R24 7030003280 S. RESISTOR ERJ3GEYJ 470 V (47 Ω) 7030003200 S. RESISTOR ERJ3GEYJ 100 V (10 Ω) R25 ERJ3GEYJ 470 V (47 Ω) R26 7030003280 S. RESISTOR S. RESISTOR ERJ3GEYJ 561 V (560 Ω) 7030003410 R27 ERJ3GEYJ 561 V (560 Ω) 7030003410 R28 S. RESISTOR

#### [MAIN UNIT]

REF.	ORDER			
NO.	NO.	U	ESCRIPTION	
R29	7030003520	S. RESISTOR S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 472 V (4.7 kΩ)	
R30 R31	7030003520 7030003800	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)	
R32	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)	
R33	7030003380	S. RESISTOR	ERJ3GEYJ 331 V (330 Ω)	
R34	7030003650	S. RESISTOR	ERJ3GEYJ 563 V (56 kΩ)	
R35	7030003520	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
R36 R37	7030003460 7030003680	S. RESISTOR S. RESISTOR	ERJ3GEYJ 152 V (1.5 kΩ) ERJ3GEYJ 104 V (100 kΩ)	
R38	7030003880	S. RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
1100	700000020	0.1120.01011	211000210 101 7 (100 11)	
C4	4030006670	S. CERAMIC	C1608 SL 1H 270J-T-A	
C5	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C6	4030006510	S. CERAMIC	C1608 SL 1H 0R5C-T-A	
C8 C10	4030006620 4550000460	S. CERAMIC S. TANTALUM	C1608 SL 1H 120J-T-A TESVA 1C 105M1-8L	
C10	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C13	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C14	4550003040	S. TANTALUM	TEMSVB2 0J 106M-8L	
C15	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C16	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C17 C21	4030006900 4030006560	S. CERAMIC S. CERAMIC	C1608 JB 1E 103K-T-A C1608 SL 1H 050C-T-A	
C21	4030008440	S. CERAMIC	C1608 SL 1H 1R5C-T-A	
C23	4030006600	S. CERAMIC	C1608 SL 1H 090D-T-A	
C24	4030006510	S. CERAMIC	C1608 SL 1H 0R5C-T-A	
C25	4030006560	S. CERAMIC	C1608 SL 1H 050C-T-A	
C26	4030006540	S. CERAMIC	C1608 SL 1H 030C-T-A	
C27 C29	4030006630 4030006520	S. CERAMIC S. CERAMIC	C1608 SL 1H 150J-T-A C1608 SL 1H 010C-T-A	
C30	4030006520	S. CERAMIC	C1608 SL 1H 270J-T-A	
C31	4030006510	S. CERAMIC	C1608 SL 1H 0R5C-T-A	
C32	4030006570	S. CERAMIC	C1608 SL 1H 060D-T-A	
C33	4030006520	S. CERAMIC	C1608 SL 1H 010C-T-A	
C34 C35	4030006850 4030006850	S. CERAMIC S. CERAMIC	C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A	
C36	4550002890	S. TANTALUM	TESVA 1A 225M1-8L	
C37	4550002890	S. TANTALUM	TESVA 1A 225M1-8L	
C38	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C39	4510001380	ELECTROLYTIC		
C40 C41	4030006670 4030006850	S. CERAMIC S. CERAMIC	C1608 SL 1H 270J-T-A C1608 JB 1H 471K-T-A	
C41	4030006580	S. CERAMIC	C1608 SL 1H 070D-T-A	
C43	4030006570	S. CERAMIC	C1608 SL 1H 060D-T-A	
C44	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C45	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C46	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C47 C48	4510003160 4030006850	ELECTROLYTIC S. CERAMIC	16 RC2 22 μF (D=4.0) C1608 JB 1H 471K-T-A	
C49	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C50	4510001350	ELECTROLYTIC	16 MS5 10 μF	
C51	4030006550	S. CERAMIC	C1608 SL 1H 040C-T-A	
C52	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C53	4030006850 4030006560	S. CERAMIC S. CERAMIC	C1608 JB 1H 471K-T-A C1608 SL 1H 050C-T-A	
C54 C55	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C56	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C57	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C58	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C59	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C60 C61	4010000100 4030006850	CERAMIC S. CERAMIC	DD104 SL 080D 50V C1608 JB 1H 471K-T-A	
C62	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C63	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C64	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C65	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C66	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A	
C67 C68	4030006850 4030006850	S. CERAMIC S. CERAMIC	C1608 JB 1H 471K-T-A	
555	70000000	J. JEHAMIO	S — Surface mount	

S.=Surface mount

### [MAIN UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
C70	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C71	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C72	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C73	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C74	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C75	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C77	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C78	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C79	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C80	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C81	4550000460	S. TANTALUM	TESVA 1C 105M1-8L
C82	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C83	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C84	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C85	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C86	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C87	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C88	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C89	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A
C90	4510001350	ELECTROLYTIC	
C91	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C93	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C94	4030006550	S. CERAMIC	C1608 SL 1H 040C-T-A
C95	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A
C98	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C99	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C100	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C101	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C102	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C103	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C104	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C105	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
C106	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A C1608 JB 1H 471K-T-A
C107	4030006850	S. CERAMIC	C1608 JB IH 4/1K-1-A
EP3	0910033640	РСВ	B 3332 (MAIN)

#### [AF UNIT]

[/ 0.	Al Olding				
REF. NO.	ORDER NO.	D	ESCRIPTION		
R8	7030003480	S. RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)		
R9	7030003800	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)		
R10	7030003320	S. RESISTOR	ERJ3GEYJ 101 V (100 Ω)		
R13	7030003200	S. RESISTOR	ERJ3GEYJ 100 V (10 Ω)		
R14	7030003420	S. RESISTOR	ERJ3GEYJ 681 V (680 Ω)		
R15	7030003420	S. RESISTOR	ERJ3GEYJ 681 V (680 Ω)		
R16	7030003600	S. RESISTOR	ERJ3GEYJ 223 V (22 kΩ)		
R18	7030003760	S. RESISTOR	ERJ3GEYJ 474 V (470 kΩ)		
R19	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)		
R20	7030003340	S. RESISTOR	ERJ3GEYJ 151 V (150 Ω)		
R21	7030003520	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)		
C1	4030006900	S. CERAMIC	C1608 JB 1E 103K-T-A		
C2	4030006900	S. CERAMIC	C1608 JB 1E 103K-T-A		
C3	4030006870	S. CERAMIC	C1608 JB 1H 222K-T-A		
C4	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A		
C5	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A		
C6	4030005110	S. CERAMIC	C2012 JB 1E 473K-T-A		
C7	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A		
C10	4510001340	ELECTROLYTIC	10 MS5 33 μF		
C11	4030005110	S. CERAMIC S. CERAMIC	C2012 JB 1E 473K-T-A C1608 JB 1H 471K-T-A		
C12	4030006850 4510003180	ELECTROLYTIC			
C13 C14	4550003180	S. TANTALUM	TESVA 0G 475M1-8L		
C15	4030005290	S. CERAMIC	C1608 JB 1H 102K-T-A		
C16	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A		
C17	4030005110	S. CERAMIC	C2012 JB 1E 473K-T-A		
C19	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A		
C20	4550002950	S. TANTALUM	TESVA 0J 335M1-8L		
C21	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A		
EP1	0910034067	РСВ	B 2014G (AF)		
EP2	6910003110	LEADFRAM	HFB2.0-0.7-8 (N)		

## [AF UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
IC1	1110001810	S. IC	TA7368F (TP1)
Q1 Q2 Q3 Q4 Q5 Q6	1530002060 1530002060 1590000520 1520000270 1530002060	S. TRANSISTOR S. FET S. TRANSISTOR S. TRANSISTOR	2SC4081 T107 R 2SC4081 T107 R 2SJ106-GR (TE85R) 2SB1182 TL Q 2SC4081 T107 R 2SC4081 T107 R
D1	1160000050	S. DIODE	DAP202U T107
R1 R2 R3 R4 R5 R6 R7	7030003580 7030003700 7030003760 7030003560 7030003480 7030003630 7030003630	S. RESISTOR	ERJ3GEYJ 153 V (15 kΩ) ERJ3GEYJ 154 V (150 kΩ) ERJ3GEYJ 474 V (470 kΩ) ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 393 V (39 kΩ) ERJ3GEYJ 393 V (39 kΩ)

#### S.=Surface mount

### [MIC UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
IC1	1110002490	S. IC	M5218FP-73A
Q1 Q2	1590000430 1590000720	S. TRANSISTOR S. TRANSISTOR	DTC144EU T107 DTA144EU T107
R1 R2 R3 R4	7030003640 7030003880 7030003710 7030003330 7030003370	S. RESISTOR S. RESISTOR S. RESISTOR S. RESISTOR	ERJ3GEYJ 244 V (240 kΩ) ERJ3GEYJ 184 V (180 kΩ) ERJ3GEYJ 121 V (120 Ω) (#04, #07, #09) ERJ3GEYJ 271 V (270 Ω)
R5 R6 R7 R8 R9 R10 R11 R12	7030003670 7030003720 7030003680 7030003740 7030003630 7030003630 7030003440 7030003710	S. RESISTOR	(#05) ERJ3GEYJ 823 V (82 kΩ) ERJ3GEYJ 104 V (220 kΩ) ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 334 V (330 kΩ) ERJ3GEYJ 393 V (39 kΩ) ERJ3GEYJ 393 V (39 kΩ) ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 184 V (180 kΩ)

## [MIC UNIT]

REF. NO.         ORDER NO.         DESCRIPTION           R13         7310002600         S. TRIMMER         RV-110 (RH03A3AS4X0AA) 47 (RH03A3AS4X0AA) 47 (RH03A3AS4X0AA) 47 (RH03A3AS4X0AA) 47 (RH05A3AS4X0AA) 47 (RH05A3AS4X0AA	
R14	
R15	<b>'</b> 3
R15	kΩ)
R17 7030003570 S. RESISTOR ERJ3GEYJ 123 V (12)  C1 4030006860 S. CERAMIC C1608 JB 1H 102K-T C3 4030006860 S. CERAMIC C1608 JB 1H 472K-T C4 4030006850 S. CERAMIC C1608 JB 1H 471K-T C5 4030006850 S. CERAMIC C1608 JB 1H 471K-T C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	3 kΩ)
C1 4030006860 S. CERAMIC C1608 JB 1H 102K-T C3 4030006880 S. CERAMIC C1608 JB 1H 472K-T C4 4030006850 S. CERAMIC C1608 JB 1H 471K-T C5 4030006850 S. CERAMIC C1608 JB 1H 471K-T C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	
C3 4030006880 S. CERAMIC C1608 JB 1H 472K-T C4 4030006850 S. CERAMIC C1608 JB 1H 471K-T C5 4030006850 S. CERAMIC C1608 JB 1H 471K-T C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	kΩ)
C3 4030006880 S. CERAMIC C1608 JB 1H 472K-T C4 4030006850 S. CERAMIC C1608 JB 1H 471K-T C5 4030006850 S. CERAMIC C1608 JB 1H 471K-T C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	-Δ
C4 4030006850 S. CERAMIC C1608 JB 1H 471K-T C5 4030006850 S. CERAMIC C1608 JB 1H 471K-T C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	
C5 4030006850 S. CERAMIC C1608 JB 1H 471K-T C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	
C6 4550000530 S. TANTALUM TESVA 1V 104M1-8L	
**	~
C6   4550000550   S. TANTALUM TESVA 1V 224M1-8L (#04, #07, #09)	
C7 4030008470 S. CERAMIC C1608 JB 1H 272K-T	-A
C8 4030006900 S. CERAMIC C1608 JB 1E 103K-T	A
C9 4030006760 S. CERAMIC C1608 SL 1H 121J-T-	A
C10 4510001850 ELECTROLYTIC 16 MS5 4R7 μF	
C11 4030006900 S. CERAMIC C1608 JB 1E 103K-T-	A
C12 4030006850 S. CERAMIC C1608 JB 1H 471K-T	-A
C13 4030006850 S. CERAMIC C1608 JB 1H 471K-T	-A
EP1 0910034014 PCB B 1922D (MIC)	
EP2 6910003110 LEADFRAM HFB2.0-0.7-8 (N)	
212 301000110 2275111111	

#### [APC UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
Q1	1520000270	S. TRANSISTOR	
Q2	1530002280		2SC4081 T107 S
Q3	1590000620	S. TRANSISTOR	
Q4	1520000270	S. TRANSISTOR	
Q5	1530002280	S. IRANSISTOR	2SC4081 T107 S
D1	1750000130	S. DIODE	DA204U T107
D2	1160000050	S. DIODE	DAP202U T107
<b>I</b>			
R1	7030003520	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R2	7030003770	S. RESISTOR	ERJ3GEYJ 564 V (560 kΩ)
R3	7030003600	S. RESISTOR S. RESISTOR	ERJ3GEYJ 223 V (22 kΩ) ERJ3GEYJ 223 V (22 kΩ)
R6 R7	7030003600 7030003670	S. RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R8	7030003440	S. RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R9	7030003440	S. RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R11	7030003440	S. RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R12	7030003480	S. RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)
R13	7030000440	S. RESISTOR	MCR10EZHJ 3.3 kΩ (332)
C1	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C2	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C3	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C5	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C6	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C7	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A
C9	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C10	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A

### [APC UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
C11	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
EP1 EP2	0910034005 6910003110	PCB LEADFRAM	B 1921E (APC) HFB2.0-0.7-8 (N)

#### [REG UNIT]

IKEG (	2141.1		
REF. NO.	ORDER NO.	ID	ESCRIPTION
IC1	1180000530	S. IC	S-81250HG-RD-T1
IC2	1130004170	S. IC	TC4S01F (TE85R)
IC3	1130004170	S. IC	TC4S01F (TE85R)
Q1 Q2 Q3 Q4 Q5 Q6	1530002280 1510000510 1530002280 1520000200 1530002280 1510000500	S. TRANSISTOR S. TRANSISTOR S. TRANSISTOR S. TRANSISTOR	2SC4081 T107 S 2SA1576 T107 R 2SC4081 T107 S 2SB798-T2 DK 2SC4081 T107 S 2SA1162-GR (TE85R)
D1	1750000160	S. DIODE	DA114 T107
D2	1750000160	S. DIODE	DA114 T107
D3	1750000160	S. DIODE	DA114 T107
R1	7030003400	S. RESISTOR	ERJ3GEYJ 471 V (470 Ω)
R2	7030003520	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R3	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R7	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R8	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
C1 C2 C3 C4 C5 C6 C7 C8 C9 C10	4030006850 4510003160 4030006850 4510001320 4030006850 4510003190 4030006850 4030006850 4030006850 4030006850 4510003190	S. CERAMIC ELECTROLYTIC S. CERAMIC ELECTROLYTIC S. CERAMIC ELECTROLYTIC S. CERAMIC ELECTROLYTIC	C1608 JB 1H 471K-T-A 16 RC2 22 μF (D=4.0) C1608 JB 1H 471K-T-A 6R3 MS5 47 μF C1608 JB 1H 471K-T-A 6.3 RC2 47 μF (D=4.0) C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A
EP1	0910034026	PCB	B 1923F (REG)
EP2	6910003110	LEADFRAM	HFB2.0-0.7-8 (N)

S.=Surface mount

## [IO UNIT]

REF. NO.	ORDER NO.	DI	ESCRIPTION
IC1	1130000830	S. IC	μPD4094BG-T1
IC2	1130000830	S. IC	μPD4094BG-T1
IC3	1130004170	S. IC	TC4S01F (TE85R)
Q1	1590000430		DTC144EU T107
Q2	1590000430		DTC144EU T107
R2	7030003700	S. RESISTOR	ERJ3GEYJ 154 V (150 kΩ)
R3	7030003680	S. RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R4	7030003720	S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
R5	7310002580	S. TRIMMER	RV-108
R6 R7	7030003620 7030003720	S. RESISTOR S. RESISTOR	(RH03A3A15X05A) 104 ERJ3GEYJ 333 V (33 kΩ) ERJ3GEYJ 224 V (220 kΩ)
C1	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A
EP1	0910034074	PCB	B 2070D (IO)
EP2	0910034091	PCB	B 2163A (IO)
EP3	6910003110	LEADFRAM	HFB2.0-0.7-8 (N)
EP4	6510008580	LEADFRAM	PT2.0-0.7-16.5 (K)

#### [PRT UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
Q1 Q2 Q3	1520000200 1530002280 1590000840	S. TRANSISTOR S. TRANSISTOR S. TRANSISTOR	2SC4081 T107 S
 D1 D2	1750000130 1790000680		DA204U T107 SB20-03P-TD
R1 R2	7030000110 7030000500	S. RESISTOR S. RESISTOR	MCR10EZHJ 5.6 Ω (5R6) MCR10EZHJ 10 kΩ (103)
C1 C2 C3 C4 C5	4030006850 4030008630 4030006850 4030006850 4030006850	S. CERAMIC S. CERAMIC S. CERAMIC S. CERAMIC S. CERAMIC	C1608 JB 1H 471K-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A
EP1	0910033442	РСВ	B 3327B (PRT)

### [DET UNIT]

NO.	NO. 1120001650		ESCRIPTION
IC1	1120001650		<del> </del>
		S. IC	TK10487MTR
Q1 Q2	1530002280 1530002020	S. TRANSISTOR S. TRANSISTOR	2SC4081 T107 S 2SC3770-3-TA
D1	1750000070	S. DIODE	1SS226 (TE85R)
X1 X2	607000060 6050005010	DISCRIMINATOR XTAL	CDBM455C7 CR-214
FI1	2020000550	CERAMIC	CFUM455E
R1 R2 R3 R4 R5	7030003480 7030003440 7030003520 7030003460 7310002590	S. RESISTOR S. RESISTOR S. RESISTOR S. RESISTOR S. TRIMMER	ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 152 V (1.5 kΩ) RV-109 (RH03A3AJ3X0BA) 222
R20 R23 R28 R30 R31 R32	7030003550 7030003560 7030003480 7030003400 7030003520 7030003520 7030003680 7030003800 7030003400 7030003400 7030003320 7030003710 7030003640 7030003640 7030003640 7030003730	S. RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ) ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 105 V (1 MΩ) ERJ3GEYJ 393 V (39 kΩ) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 152 V (1.5 kΩ) ERJ3GEYJ 152 V (1.5 kΩ) ERJ3GEYJ 274 V (270 kΩ)
C2 C3 C4 C5 C6 C7 C8 C10 C11 C12 C13 C14 C15 C16 C17 C19 C24 C25 C26 C27 C28 C29	4030004760 4030006740 4030004760 4030004760 4030006640 4030006640 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006890 403000680 4030006890 4030006890 4030006890 4030006890 4030006890 4030006890 4030006890 4030006890	S. CERAMIC	C2012 JF 1E 104Z-T-A C1608 SL 1H 820J-T-A C2012 JF 1E 104Z-T-A C2012 JF 1E 104Z-T-A C2012 JF 1E 104Z-T-A C1608 SL 1H 180J-T-A C1608 SL 1H 560J-T-A C1608 JB 1H 102K-T-A C1608 JF 1H 103Z-T-A

S.=Surface mount

## [RF UNIT]

	REF. NO.	ORDER NO.	DESCRIPTION		
	Q1	1530002620	S. TRANSISTOR	2SC3585 R44-T2B	
	Q2	1530002620		2SC3585 R44-T2B	
-	D1	1790000620	S. DIODE	MA77 (TW)	
	D2 D3	1790000620 1790000620	S. DIODE S. DIODE	MA77 (TW) MA77 (TW)	
-	D3 D4	1790000620	S. DIODE	MA77 (TW)	
-					
	L1	6190000320	COIL	5HW-F367PN-157A	
	L2	6190000320	COIL	5HW-F367PN-157A	
	L3	6200000720	S. COIL	LQN 2A 10NM	
	D4	7000000500	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
	R1 R2	7030003520 7030003470	S. RESISTOR	ERJ3GEYJ 182 V (1.8 kΩ)	
-	R3	7030003620	S. RESISTOR	ERJ3GEYJ 333 V (33 kΩ)	
-	R4	7030003280	S. RESISTOR	ERJ3GEYJ 470 V (47 Ω)	
-	R5 R6	7030003280 7030003620	S. RESISTOR S. RESISTOR	ERJ3GEYJ 470 V (47 Ω) ERJ3GEYJ 333 V (33 kΩ)	
	R7	7030003620	S. RESISTOR	ERJ3GEYJ 471 V (470 Ω)	
-	R8	7030003280	S. RESISTOR	ERJ3GEYJ 470 V (47 Ω)	
	R9	7030003520	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
	R10	7030003520	S. RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
	C2	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
	C3	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
	C4	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
	C5	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A	
	C6 C7	4030006850 4030006850	S. CERAMIC S. CERAMIC	C1608 JB 1H 471K-T-A	
-	C8	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A	
	EP1	0910020033	РСВ	B 1916C (RF)	
-	EP1	0910034045	PCB	(#04, #05, #07) B 1950E (RF) (#09)	
	EP1	0910034045	PCB	B 1950E (RF)	
	EP3	6910003110	LEADFRAM	HFB2.0-0.7-8 (N)	
1					

### [PLL UNIT]

[1 FF 6	ILE ORILI			
REF. NO.	ORDER NO.		DESCRIPTION	
R7	7030003380	S. RESISTOR	ERJ3GEYJ 331 V (330 Ω)	
R8	7030003620	S. RESISTOR	ERJ3GEYJ 333 V (33 kΩ)	
R11	7030003440	S. RESISTOR	ERJ3GEYJ 102 V (1 kΩ)	
R13	7030003440	S. RESISTOR	ERJ3GEYJ 102 V (1 kΩ)	
R20	7030003320	S. RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R21	7030003640	S. RESISTOR	ERJ3GEYJ 473 V (47 kΩ)	
R23	7030003360	S. RESISTOR	ERJ3GEYJ 221 V (220 Ω)	
R24	7030003630	S. RESISTOR	ERJ3GEYJ 393 V (39 kΩ)	
R26	7030003630	S. RESISTOR	ERJ3GEYJ 393 V (39 kΩ)	
R27	7030003550	S. RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)	
R28	7030003540	S. RESISTOR	ERJ3GEYJ 682 V (6.8 kΩ)	
R29	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)	
R30	7030003720	S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)	
1100	7000007.20	0. 112013 . 3	assessment and a party	
C8	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C11	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C12	4030006550	S. CERAMIC	C1608 SL 1H 040C-T-A	
C13	4030006860	S. CERAMIC	C1608 JB 1H 102K-T-A	
C15	4030007080	S. CERAMIC	C1608 CH 1H 390J-T-A	
C16	4030007030	S. CERAMIC	C1608 CH 1H 150J-T-A	
C17	4610001260	S. TRIMMER	ECR-JA020 E12W	
C19	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A	
C20	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C21	4030006900	S. CERAMIC	C1608 JB 1E 103K-T-A	
C26	4030008440	S. CERAMIC	C1608 SL 1H 1R5C-T-A	
C27	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C28	4030006580	S. CERAMIC	C1608 SL 1H 070D-T-A	
C29	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A	
C30	4030006540	S. CERAMIC	C1608 SL 1H 030C-T-A	
C31	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A	
C32	4550000460	S. TANTALUM	TESVA 1C 105M1-8L	
C39	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A	
C40	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A	
C41	4030004760	S. CERAMIC	C2012 JF 1E 104Z-T-A	
C43	4550000460	S. TANTALUM	TESVA 1C 105M1-8L	
C44	4030006560	S. CERAMIC	C1608 SL 1H 050C-T-A	
C45	4030006590	S. CERAMIC	C1608 SL 1H 080D-T-A	
EP1	0910022905	PCB	B 2242E (PLL)	
	1			

#### [PLL UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
IC1	1120001550	S. IC	M54959FP
IC2	1130004200	S. IC	TC4S66F (TE85R)
Q2	1530002560	S. TRANSISTOR	2SC4403-3-TR
Q3	1530002560	S. TRANSISTOR	
Q4	1530002560	S. TRANSISTOR	
Q6	1560000540	S. FET	
X1	6050005790	XTAL	CR-257
L2	6200000110	S. COIL	LQN 2A 33NM
L4	620000090	S. COIL	LQN 2A 18NM
L5	620000090	S. COIL	LQN 2A 18NM

#### [VCO UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
Q1	1530000371	S. TRANSISTOR	2SC3356 R25-T2B
D1	1790000530	S. VARICAP	MA333 (TW)
D2	1790000620	S. DIODE	MA77 (TW)
D3	1790000620	S. DIODE	MA77 (TW)
L1	6110002000	COIL	LA-226
L2	6200000360	S. COIL	MLF3216D R33M-T
R1	7030003440	S. RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R3	7030003720	S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
R4	7030003580	S. RESISTOR	ERJ3GEYJ 153 V (15 kΩ)
R5	7030003580	S. RESISTOR	ERJ3GEYJ 153 V (15 kΩ)
R6	7030003640	S. RESISTOR	ERJ3GEYJ 473 V (47 kΩ)

S.=Surface mount

## [VCO UNIT]

-	_		
REF. NO.	ORDER NO.		ESCRIPTION
R7 R8 R9 R10	7030003540 7030003360 7030003520 7030003350	S. RESISTOR S. RESISTOR S. RESISTOR S. RESISTOR	ERJ3GEYJ 221 V (220 Ω) ERJ3GEYJ 472 V (4.7 kΩ)
C1 C2 C3 C4 C5 C6 C7 C8 C9 C10 C11 C12 C13 C14	4030006910 4030006900 4610001260 4030007010 4030007030 4030006850 4030006850 4030007020 4550000460 4030007010 4030006920 4030006930	S. CERAMIC S. CERAMIC S. TRIMMER S. CERAMIC	C1608 CH 1H 0R5C-T-A C1608 JB 1E 103K-T-A ECR-JA020 E12W C1608 CH 1H 100D-T-A C1608 CH 1H 150J-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 CH 1H 120J-T-A TESVA 1C 105M1-8L C1608 CH 1H 100D-T-A C1608 CH 1H 100D-T-A C1608 CH 1H 010C-T-A C1608 CH 1H 010C-T-A
EP1	0910022924	РСВ	B 2241D (VCO)

### [MTB UNIT]

REF. NO.	ORDER NO.	DI	ESCRIPTION
IC1	1110001971	S. IC	μPC1676G-T1
Q1	1590000650	S. TRANSISTOR	DTA144TU T107
Q2	1590000740	S. TRANSISTOR	FMA4 T148
D2	1790000450	S. DIODE	MA862 (TX)
D3	1790000450	S. DIODE	MA862 (TX)
D4	1790000450	S. DIODE	MA862 (TX)
D5	1160000060	S. DIODE	DAN202U T107
L1	6200000720	S. COIL	LQN 2A 10NM
L2	6200000720	S. COIL	LQN 2A 10NM
L3	6200000100	S. COIL	LQN 2A 22NM
L4	6200000110	S. COIL	LQN 2A 33NM
R1 R2 R3 R4 R5 R6 R7 R8	7030003240 7030003640 7030003520 7030003520 7030003520 7030003480 7030003640 7030003470	S. RESISTOR	ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 222 V (2.2 kΩ)
C1	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C2	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C3	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C4	4030006890	S. CERAMIC	C1608 JF 1H 103Z-T-A
C5	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
C6	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A

#### S.=Surface mount

## [MTB UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C7 C8 C9 C10 C11 C12 C13 C14 C15 C16 C17	4030008440 4030008440 4030006550 4030006600 4030006620 4030006620 4030006830 4030006850 4030006850 4030006850	S. CERAMIC	C1608 SL 1H 1R5C-T-A C1608 SL 1H 1R5C-T-A C1608 SL 1H 040C-T-A C1608 SL 1H 090D-T-A C1608 SL 1H 120J-T-A C1608 SL 1H 120J-T-A C1608 SL 1H 185C-T-A C1608 SL 1H 150J-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A
EP1 EP2	0910034083 6910003110	PCB LEADFRAM	B 2071C (MTB) HFB2.0-0.7-8 (N)

# [LOGIC UNIT]

DEC	ORDER		
REF. NO.	NO.	Di	ESCRIPTION
IC1	1140002350	S. IC	HD404629A02H
1			(#04, #05, #09)
IC1	1140002680	S. IC	HD404629A12H (#07)
IC2	1110002410	S. IC	NJM2406F (TE1)
1C3	1130003760	S. IC	TC4S81F (TE85R)
IC4	1130006210	S. IC	MN1382P (TX)
Q1	1560000540	S. FET	2SK880-Y (TE85R)
Q3	1530002060		2SC4081 T107 R
Q3 Q4	1510000510		2SA1576 T107 R
1	1590000660		DTC144TU T107
Q5		i	DTC144TU T107
Q6	1590000660		DTA144TU T107
Q7	1590000650		
Q8	1590000720	S. IHANSISTOR	DTA144EU T107
D1	1790000990	S. ZENER	MA8051-H (TX)
D2	1160000060	S. DIODE	DAN202U T107
D3	1750000130	S. DIODE	DA204U T107
D4	1750000130	S. DIODE	DA204U T107
D5	1790000590	S. DIODE	MA110 (TW)
D6	1790000870	S. DIODE	MA1S121 (TX)
D9	1790000870	S. DIODE	MA1S121 (TX)
D13	1160000060	S. DIODE	DAN202U T107
D15	1750000130	S. DIODE	DA204U T107
D17	1160000060	S. DIODE	DAN202U T107 (#05)
D17	1750000160	S. DIODE	DA114 T107
"	(	0. 2.022	(#04, #07, #09)
D18	1790000590	S. DIODE	MA110 (TW)
D19	1750000160	S. DIODE	DA114 T107 (#04)
D20	1790000660	S. DIODE	MA728 (TW)
X1	6060000390	CERAMIC	CSB800J201
X2	6050005801	XTAL	DS-VT200 (32.768 KHz±20)
R1	7030003460	S. RESISTOR	ERJ3GEYJ 152 V (1.5 kΩ)
R2	7030003380	S. RESISTOR	ERJ3GEYJ 331 V (330 Ω)
R3	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R5	7030003640	S. RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R6	7030003650	S. RESISTOR	ERJ3GEYJ 563 V (56 kΩ)
1			

### [LOGIC UNIT]

	REF. NO.	ORDER NO.	C	DESCRIPTION
ĺ	R7	7030003690	S. RESISTOR	ERJ3GEYJ 124 V (120 kΩ)
	R8	7030003590	S. RESISTOR	ERJ3GEYJ 183 V (18 kΩ)
	R9	7410000710	S. ARRAY	EXB-V8V 224JV
	R13	7410000720	S. ARRAY	EXB-V8V 473JV
	R17	7410000700	S. ARRAY	EXB-V8V 105JV
	R21	7030003480	S. RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)
	R22	7030003340	S. RESISTOR	ERJ3GEYJ 151 V (150 Ω)
	R23	7030003340	S. RESISTOR	ERJ3GEYJ 151 V (150 Ω)
	R24	7030003450	S. RESISTOR	ERJ3GEYJ 122 V (1.2 kΩ)
i	R25	7030003450	S. RESISTOR	ERJ3GEYJ 122 V (1.2 kΩ) ERJ3GEYJ 824 V (820 kΩ)
	R26	7030003790	S. RESISTOR	ERJ3GEYJ 394 V (390 kΩ)
	R27	7030003750 7030003720	S. RESISTOR S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
ı	R28 R29	7030003720	S. RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
	R30	7030003660	S. RESISTOR	ERJ3GEYJ 683 V (68 kΩ)
	R31	7030003760	S. RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
	R32	7030003580	S. RESISTOR	ERJ3GEYJ 153 V (15 kΩ)
	R33	7030003580	S. RESISTOR	ERJ3GEYJ 153 V (15 kΩ)
	R34	7030003760	S. RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
	R35	7310003600	S. TRIMMER	EVM-1XSX50 B54 (503)
	R36	7030003800	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
	R37	7030003580	S. RESISTOR	ERJ3GEYJ 153 V (15 kΩ)
	R38	7030003610	S. RESISTOR	ERJ3GEYJ 273 V (27 kΩ)
	R43	7030003600	S. RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
	R44	7030003640	S. RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
	D45	7010000010	C TOWNED	(#04) EVM-1XSX50 B14 (103)
	R45 R46	7310003610 7030003800	S. TRIMMER S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
	F140	7030003600	S. NESISTON	(#04)
	R47	7410000710	S. ARRAY	EXB-V8V 224JV
	R49	7030003360	S. RESISTOR	ERJ3GEYJ 221 V (220 Ω)
	R50	7030003720	S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
	R51	7030003760	S. RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
	R52	7030003800	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
	R53	7030003200	S. RESISTOR	ERJ3GEYJ 100 V (10 Ω)
	R54	7030003800	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
	R55	7410000590	S. ARRAY	EXB-V4V 473JV
	R57	7030003720	S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
	R58	7410000580	S. ARRAY	EXB-V4V 224JV
1	R59	7030003800	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ) ERJ3GEYJ 333 V (33 kΩ)
	R63	7030003620 7030003720	S. RESISTOR S. RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
	R64 R65	7030003720	S. RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
	R66	7030003560	S. RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
	1100	, 00000000		
	C1	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
	C2	4030008630	S. CERAMIC	C1608 JF 1C 104Z-T-A
	C3	4550000770	S. TANTALUM	TESVC 0J 226M-12L
	C4	4030008630	S. CERAMIC	C1608 JF 1C 104Z-T-A C1608 JB 1H 471K-T-A
1	C6	4030006850 4610001290	S. CERAMIC S. TRIMMER	ECR-JA050 M12W
	C11 C12	4030006710	S. CERAMIC	C1608 SL 1H 470J-T-A
	C13	4030006800	S. CERAMIC	C1608 SL 1H 221J-T-A
	C14	4030007030	S. CERAMIC	C1608 CH 1H 150J-T-A
	C15	4030007030	S. CERAMIC	C1608 CH 1H 150J-T-A
	C16	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
1	C17	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
	C18	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
	C19	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
1	C20	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
İ	C21	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A
	C22	4030008630	S. CERAMIC	C1608 JF 1C 104Z-T-A
	C23	4030008630	S. CERAMIC	C1608 JF 1C 104Z-T-A
	C24	4030006850	S. CERAMIC	C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A
	C25 C26	4030006850 4030006710	S. CERAMIC S. CERAMIC	C1608 JB 1H 471K-1-A
	U20	4030000710	J. OLINAWIO	01000 OL 111 9700-1-A
	DS1	5030000720	LCD	LD-BU5385J (E-5561)
				[FUNCTION DISPLAY]
	DS2	5040001110	S. LED	SLM-23VMWS T97B
	DS3	5040001260	LED	LN01301C (Q) LN01301C (Q)
	DS4 DS5	5040001260 5040001260	LED LED	LN01301C (Q)
	<i>U</i> 30	30-300 (200		2.10 (00 10 (02)

### [LOGIC UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
DS6	5040001260	LED	LN01301C (Q)
S1	2260001610	s. switch	SW-134 (SKQDAB) [H/L/DTMF]
S2	2260001610	S. SWITCH	SW-134 (SKQDAB) [MONI/DSEL]
S4	2260001610	S. SWITCH	SW-134 (SKQDAB) [AI]
BT1	3020000160	LITHIUM	VL2020-1VC
MC1	7700000861	MICROPHONE	WM-62A103
SP1	2510000530	SPEAKER	T028S14I0810
EP1 EP2	0910033165 0910033280	PCB FPC	B 3328E (LOGIC) B 3329
EP4	8930023130	LCD CONTACT	SHCN-1144W
		·	
1			

## [PTT UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
S1	2260001610	S. SWITCH	SW-134 (SKQDAB) [PTT]
S2	2260001610	S. SWITCH	SW-134 (SKQDAB) [FUNC]
EP1	0910033212	PCB	B 3325B (PTT)
EP2	0910033332	FPC	B 3385B

# [ENC UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C30 C31	4030006850 4030006850	S. CERAMIC S. CERAMIC	
S1 S2	2260001400 2260001310	ENCODER S. SWITCH	SW-122 (RK097103H) [MAIN DIAL] SW-120 (SKHUPD) [LIGHT]
EP1 EP2	0910033753 0910033323	PCB FPC	B 3326C (ENC) B 3383C
L			0.0.4

S.=Surface mount

#### [TENKEY UNIT]

REF. NO.	ORDER NO.	DESCRIPTION
DS1 DS2 DS3 DS4	5010000070 5010000070 5010000070 5010000070	S. LED LT1E73A (GL1EG73) S. LED LT1E73A (GL1EG73) S. LED LT1E73A (GL1EG73) S. LED LT1E73A (GL1EG73)
EP1 EP2	0910033311 0910033291	PCB B 3358A (TENKEY) FPC B 3330A

#### [VR UNIT]

REF. NO.	ORDER NO.	DESCRIPTION				
R1	7210001440	VARIABLE	RK097111101NA (10KA) [PWR/VOL]			
R2	7210001450	VARIABLE	RK0971110051A (10KB) [SQL]			
C1 C2 C3	4030006860 4030006860 4510002650	S. CERAMIC S. CERAMIC ELECTROLYTIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A 16 MS7 100 μF			
EP1	0910034034	РСВ	B 1926D (VR)			

S.=Surface mount

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# SECTION 6 ADJUSTMENT PROCEDURES

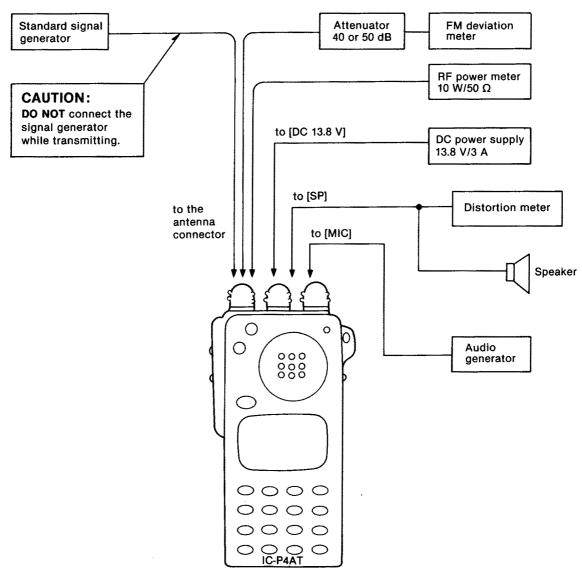
#### 6-1 PREPARATION BEFORE SERVICING

#### REQUIRED TEST EQUIPMENT

EQUIPMENT	GRADE AND RANGE	EQUIPMENT	GRADE AND RANGE		
DC power supply	Output voltage : 13.8 V DC Current capacity : 3 A or more	Audio generator	Frequency range : 300~3000 Hz Output level : 1~500 mV		
RF power meter (terminated type)	Measuring range : 1∼10 W Frequency range : 420∼460 MHz	Attenuator	Power attenuation : 40 or 50 dB Capacity : 10 W or more		
	Impedance : 50 Ω SWR : Less than 1.2:1	DC voltmeter	Input impedance : 50 kΩ/DC or better		
Frequency counter		AC millivoltmeter	Measuring range : 10 mV∼10 V		
	Frequency range : 0.1~460 MHz Frequency accuracy: ±1 ppm or better	External speaker	Impedance : 8 Ω		
	Sensitivity : 100 mV or better  Frequency range : 1 kHz±10 Hz	FM deviation meter	Frequency minimum: 460 MHz Measuring range: 0~±10 kHz		
	Measuring range : 1~100 %	Digital multimeter or	Input impedance : 1 MΩ/DC or better		
Standard signal generator (SSG)	Frequency range : 0.1~460 MHz Output level : -127~-17 dBm (0.1 μV~32 mV)	oscilloscope			

CCW: counterclockwise

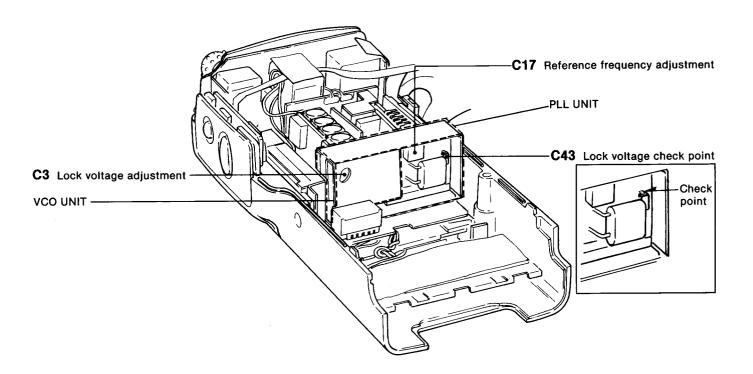
#### CONNECTION



#### 6-2 PLL ADJUSTMENT

ADJUSTMENT		AD WATER THE CONDITIONS	N	MEASUREMENT	VALUE	ADJUSTMENT POINT	
		ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
REFERENCE FREQUENCY	1	<ul> <li>Displayed frequency: 440.00 MHz</li> <li>Connect the RF power meter or a 50 Ω dummy load to the antenna connector.</li> <li>Transmitting</li> </ul>	Top panel	Loosely couple the frequency counter to the antenna connector.	440.0000 MHz	PLL	C17
LOCK VOLTAGE	1	Displayed frequency:     449.9750 MHz (USA version)     440.00 MHz (All other versions)     Simplex     Transmitting and receiving	PLL	Connect the digital multimeter or oscilloscope to C43. (+ side)	3.0 V DC on the higher voltage at transmitting or receiving	vco	C3

#### • PLL AND VCO UNITS



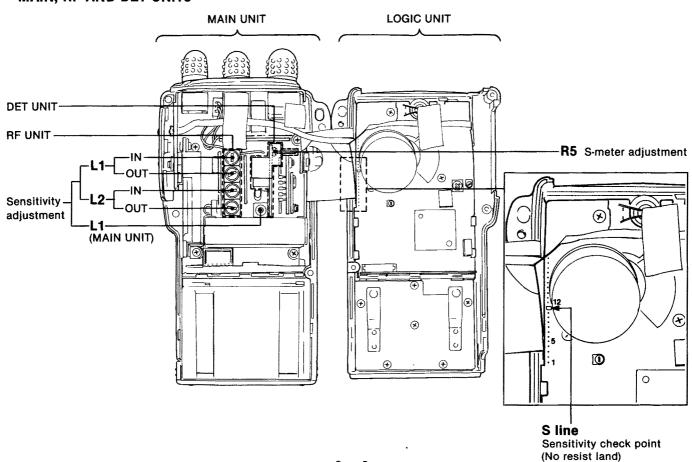
Although the above diagram has no shield cover on the PLL unit, adjustment may be performed without removing the shield cover.

### **6-3 RECEIVER ADJUSTMENT**

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
		ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
SENSITIVITY	1	Displayed frequency:  446.00 MHz (USA version)  436.00 MHz (All other versions)  [SQL] control : Max. CCW  Connect the SSG to the antenna connector and set as:  Level : 0.32 µV* (-117 dBm)  Modulation: 1 kHz  Deviation : ±3.5 kHz  Receiving		Connect the DC voltmeter to the land of the S line.	Pull out 2 rotation from coil case.	RF	L1 IN, L1 OUT, L2 IN, L2 OUT
	2				Maximum		L1 IN, L2 OUT
	3	Displayed frequency:     440.5 MHz (USA version)     430.5 MHz (All other versions)			Maximum		L1 OUT, L2 IN
						MAIN	L1
S-METER	1	<ul> <li>Displayed frequency:         445.00 MHz (USA version)         435.00 MHz (All other versions)</li> <li>Connect the SSG to the antenna connector and set as:         Level : 0.32 μV* (-117 dBm)         Modulation: 1 kHz         Deviation : ±3.5 kHz</li> <li>Receiving</li> </ul>	Function display	S/RF indicator	2 dots (S2)	DET	R5

<sup>\*</sup>This output level of the standard signal generator (SSG) is indicated as the SSG's open circuit.

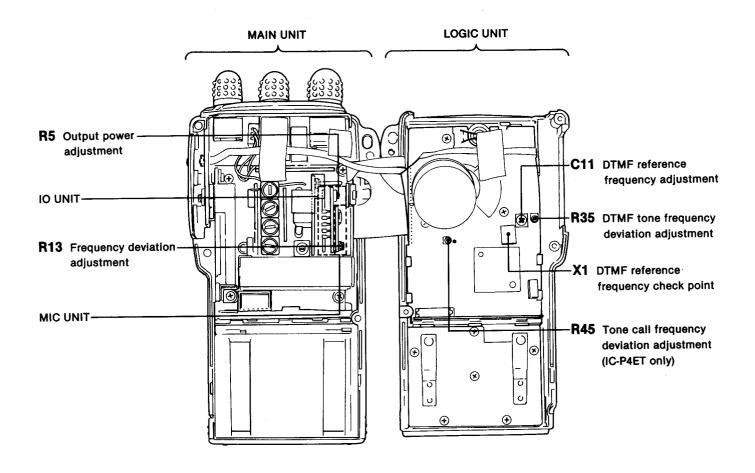
#### • MAIN, RF AND DET UNITS



# **6-4 TRANSMITTER ADJUSTMENT**

ADJUSTMENT		AD HIGHMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
ADJUSTME	N I	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
OUTPUT POWER	1	Displayed frequency:     445.00 MHz (USA version)     435.00 MHz (All other versions)     Output power : HIGH     Simplex     Transmitting	Top panel	Connect the RF power meter to the antenna connector.	5.0 W	10	R5
	2	Output power : LOW 1			0.25~1.0 W		Verify
	3	Output power : LOW 2			Approx. 1.5 W		Verify
	4	Output power : LOW 3			Approx. 3.5 W		Verify
FREQUENCY DEVIATION	1	Displayed frequency: 445.00 MHz (USA version) 435.00 MHz (All other versions) Output power : HIGH Connect the audio generator to the [MIC] jack and set as: 210 mV/1.0 kHz (USA version) 95 mV/1.0 kHz (All other versions) Set the FM deviation meter as: HPF : 50 kHz LPF : 20 kHz De-emphasis: OFF Detector : (P-P)/2 Transmitting	Top panel	Connect the FM deviation meter to the antenna connector via the attenuator.	±4.8 kHz	MIC	R13
DTMF REFERENCE FREQUENCY	1	Displayed frequency:     445.00 MHz (USA version)     435.00 MHz (All other versions)     Receiving	LOGIC	Loosely couple the frequency counter to X1 via the 800 kHz band amplifier.	792.506~807.263 kHz		Verify
		NOTE: When the obtained frequency is out the variation, adjust C11 on the LOGIC unit for 792.506~807.263 kHz.					
DTMF TONE FREQUENCY DEVIATION	1	Displayed frequency:     445.00 MHz (USA version)     435.00 MHz (All other versions)     Push and hold the [D] key while transmitting.	Top panel	Connect the FM deviation meter to the antenna connector via the attenuator.	±3.5 kHz	LOGIC	R35
TONE CALL FREQUENCY DEVIATION (IC-P4ET only)	1	<ul> <li>Displayed frequency: 435.00 MHz</li> <li>While pushing the [LIGHT], set the transceiver to transmitting.</li> </ul>	Top panel	Connec the FM deviation meter to the antenna connector via the attenuator.	±3.5 kHz	LOGIC	R45

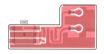
#### • 10, MIC AND LOGIC UNITS

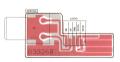


#### SECTION 7 BOARD LAYOUTS

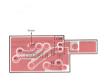
#### 7-1 LOGIC UNIT

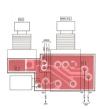
#### • ENC UNIT



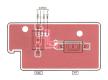


#### • VR UNIT



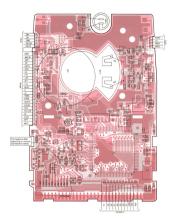


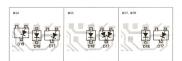
#### • PTT UNIT

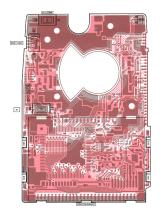


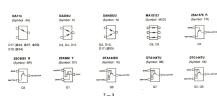
#### TENKEY UNIT







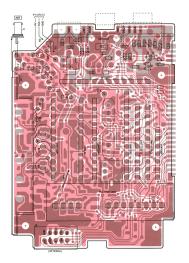




#### 7-2 MAIN UNIT

MAIN UNIT

The combination of this page and the next page show the unit layout in the same configuration as the actual P.C. Board.



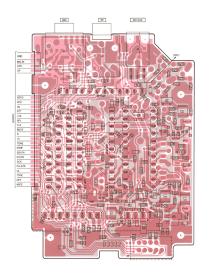






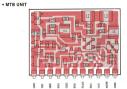








#### 7-3 MTB AND AF UNITS



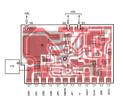


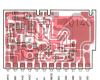






#### AF UNIT













#### 7-4 IO AND MIC UNITS

#### • 10 UNIT (IC1)





#### . IO UNIT (IC2)





#### • MIC UNIT



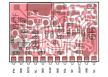


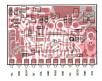




### 7-5 DET AND REG UNITS

#### DET UNIT



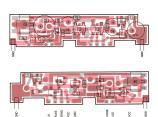








### • REG UNIT







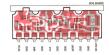


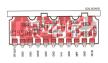




## 7-6 RF AND APC UNITS

### • RF UNIT





#### COIL BOARD





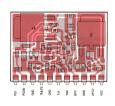
DAP202U

(Symbol: P)

2SC4081 S

(Symbol: BS)

#### APC UNIT



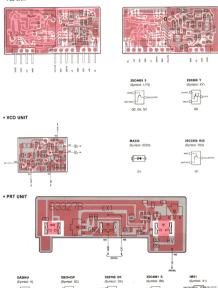


DA204U



## 7-7 PLL, VCO AND PRT UNITS

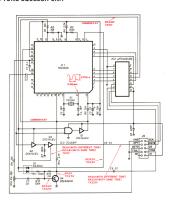
### • PLL UNIT

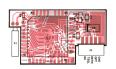


Q3

# SECTION 8 OPTIONAL UNITS

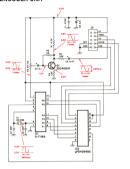
### 8-1 UT-50 TONE SQUELCH UNIT

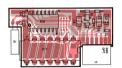


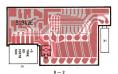




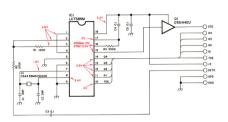
### 8-2 UT-51 TONE ENCODER UNIT







### 8-3 UT-49 DTMF DECODER UNIT





MIC

L·P·F IC1b

IC1 M5218FP

DECODER OPTIONAL OPTIONAL

TONE SOL TONE

MIC UNIT

AF7V REG 04 25B1182F5 05,06 25C4081×2

VR UNIT

AF UNIT

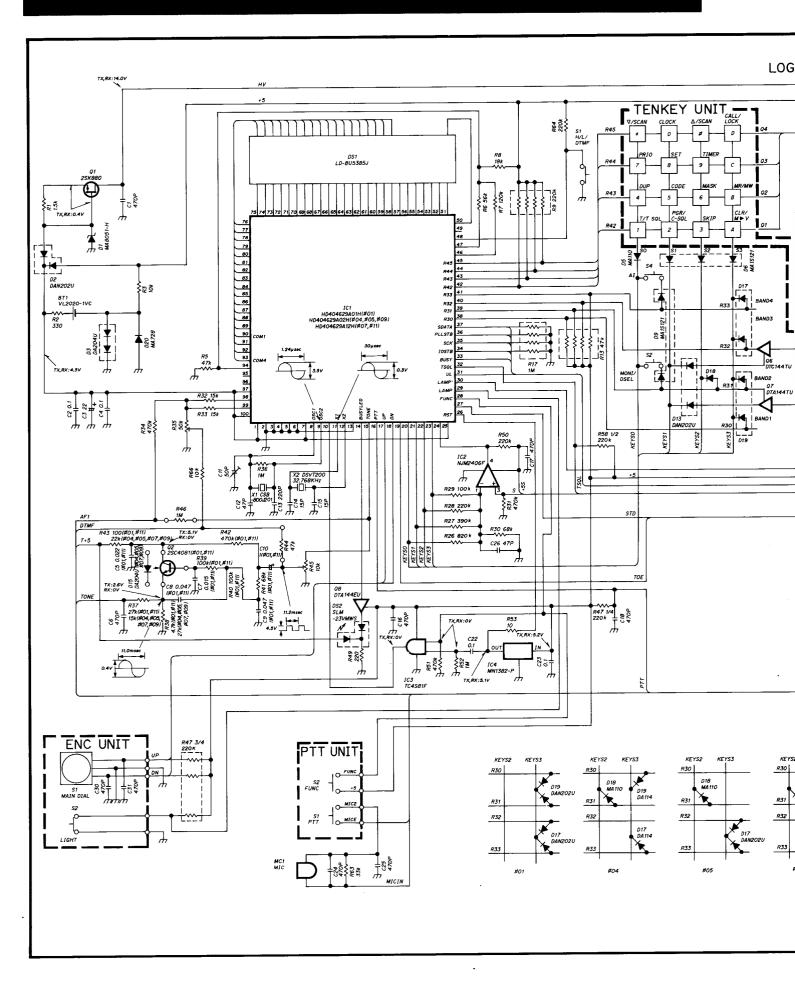
1750HZ TONE CALL

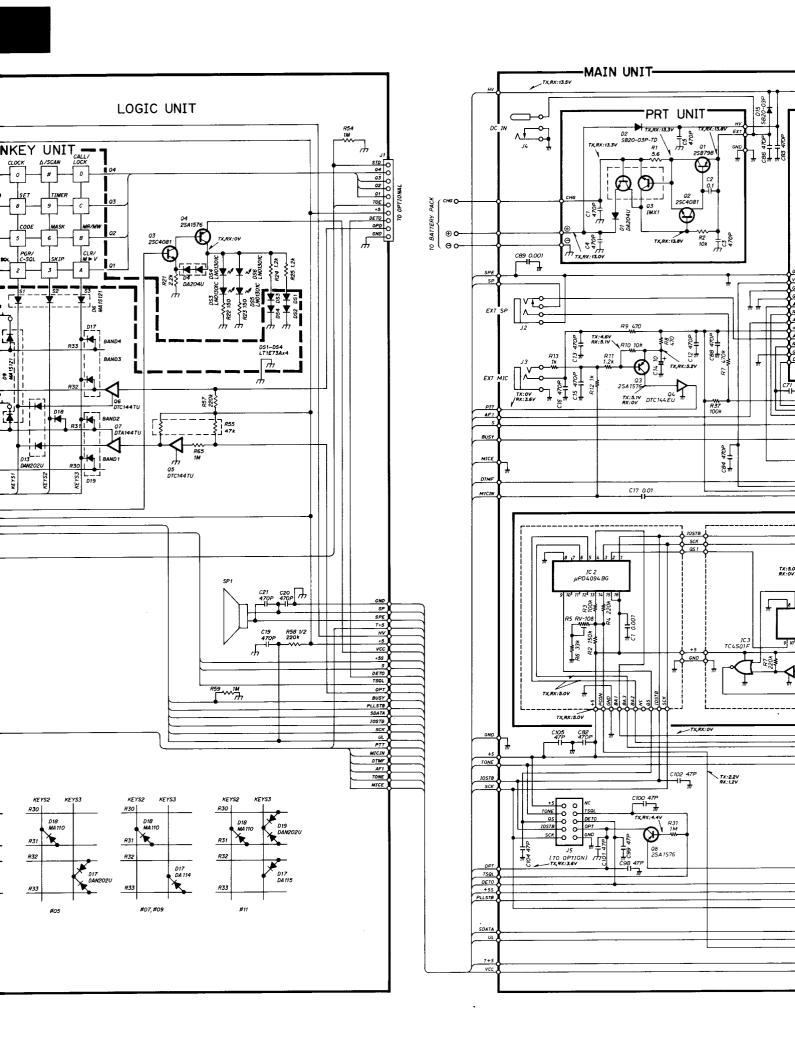
PTT CONTROL 03 2SA1576 04 DTC144EU MAIN UNIT

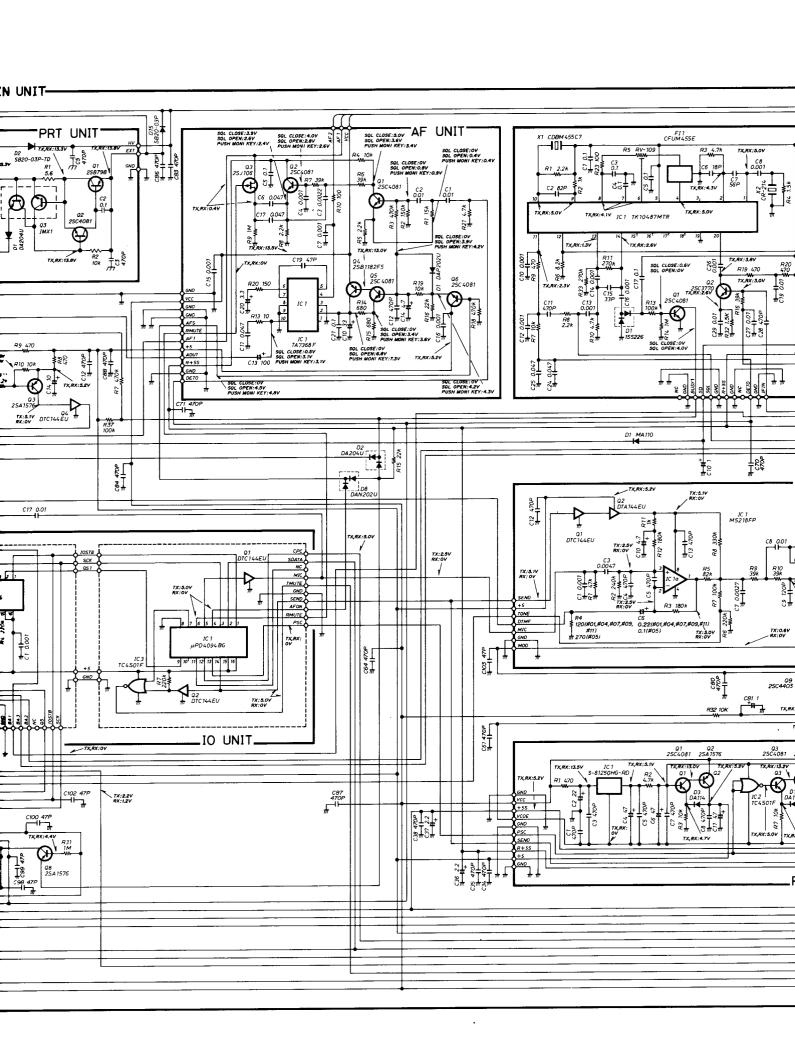
PTT UNIT

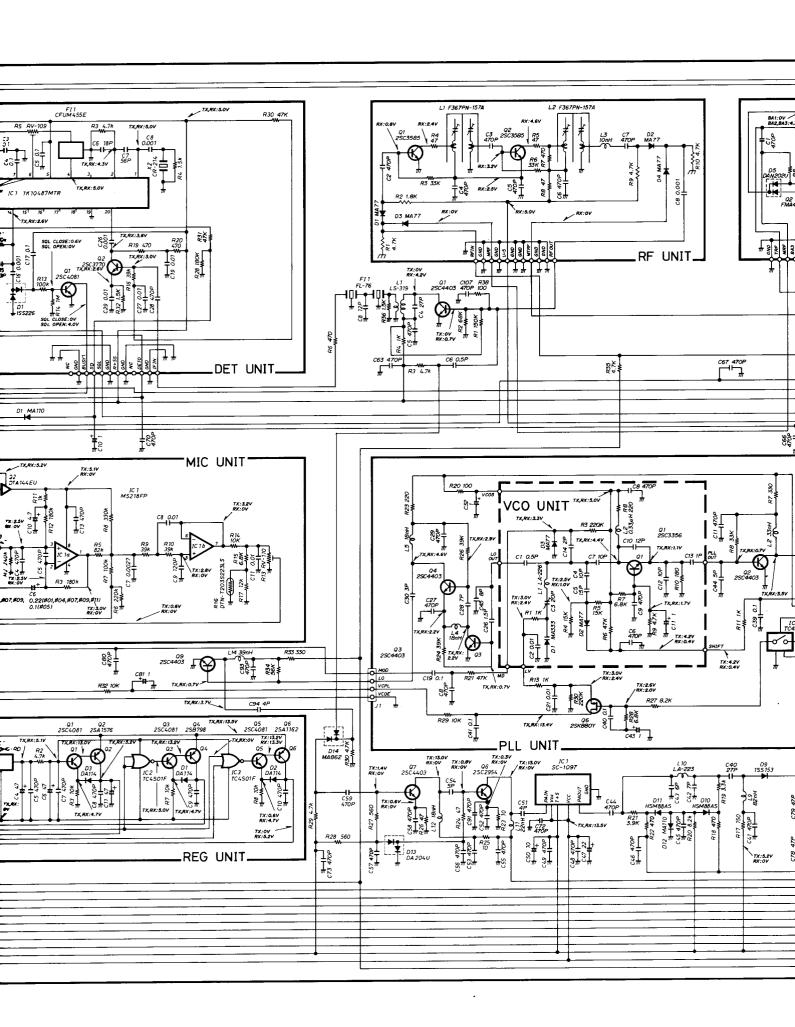
\* † ENC UNIT

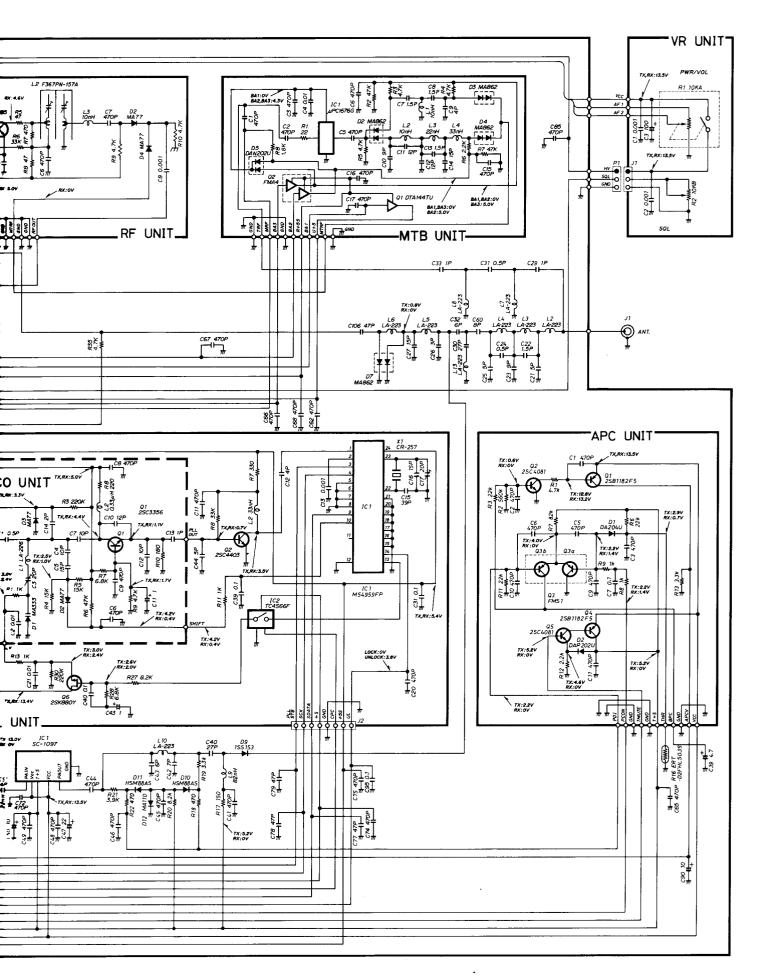
COMMON











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